

EEL3744

## Today's Menu

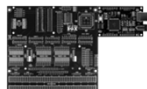
- Hardware Interfacing Concepts
- Instruction Cycle, Machine Transfers, and E-Cycles
  - > Fetch, Decode, & Execute
  - > Memory Read & Write
- Address and Data Bus Timing



See examples on  
web-site: `Input_Port.asm`

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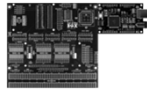
## Instruction Cycle, Machine Transfers, and E-Cycles

- An instruction cycle consists of a sequence of machine transfers. A machine transfer corresponds to a single machine operation (a single E-clock pulse) on the external buses.
- Each machine transfer is one of the following types:
 

1. Opcode Fetch	2. Memory Read
3. Memory Write	4. Execution - No Transfer.
- **6811 (non-pipelined) Example:** Each machine transfer requires 1 E-clock cycle
  - > The corresponding time depends on the frequency of the internal clock
  - > If operating with an 8-MHz crystal, the fundamental E-clock frequency is 2 MHz
    - E-clock pulse requires 500 ns (1 / 2 MHz)
    - To execute a 4 cycle instruction (e.g., STAA with extended addressing) takes  $4 \times 500 \text{ ns} = 2 \mu\text{s}$ .

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## EEL3744 6811 Hardware Interfacing Concepts

- At the beginning of each machine transfer, the E-clock pulse goes from low to high, to indicate the beginning of a cycle
  - After the operating mode has been selected using the MODA pin input immediately after RESET, the MODA/LIR (Load Instruction Register) open drain output indicates the execution of an opcode fetch machine transfer
  - LIR is low for first E-cycle of each new instruction.**
- Each type of machine transfer can be identified using a combination of these signals, as shown in the simplified table below

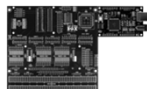
**68HC11 Machine Transfer Chart**

Machine Transfer	LIR(L)	R/~W
Opcode Fetch	Low	High
Memory Read	High	High
Memory Write	High	Low

$\overline{\text{LIR}} = \text{LIR(L)}$

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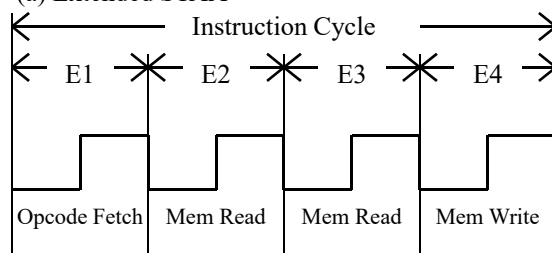


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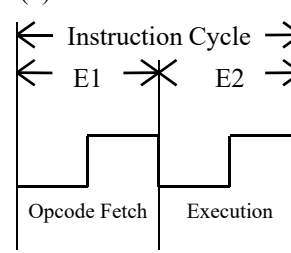
## 6811 Hardware Interfacing Concepts

- Instruction cycles, machine transfers, and E-cycles for instructions (see **6811 Reference Manual**)

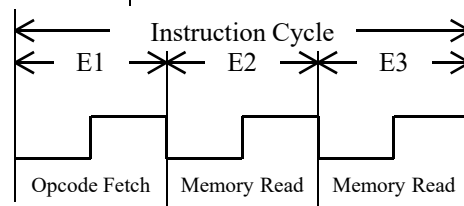
(a) Extended STAA



(b) Inherent ABA

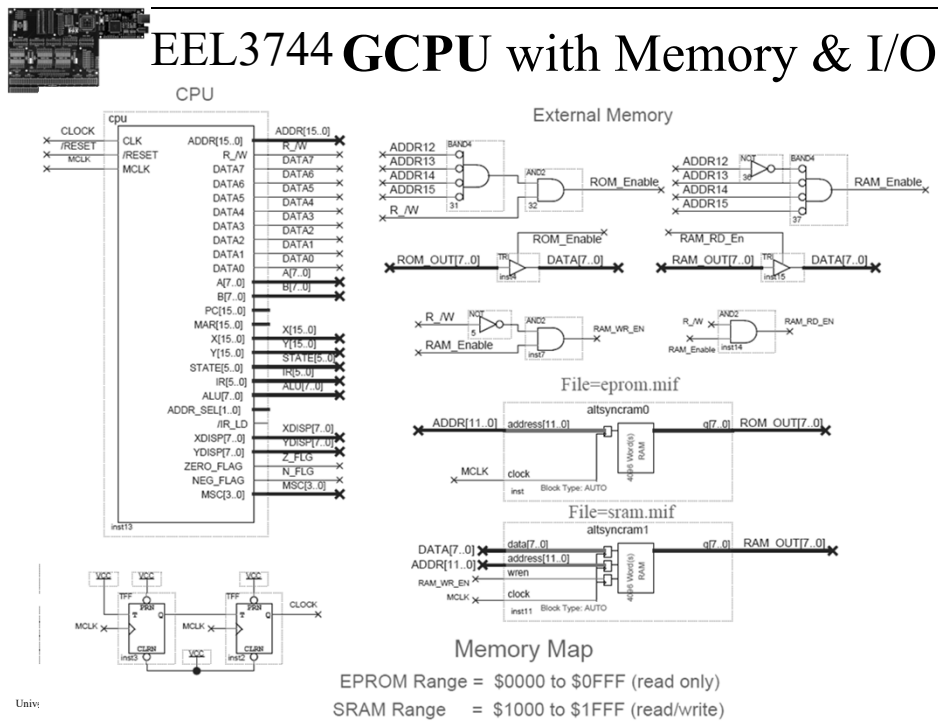
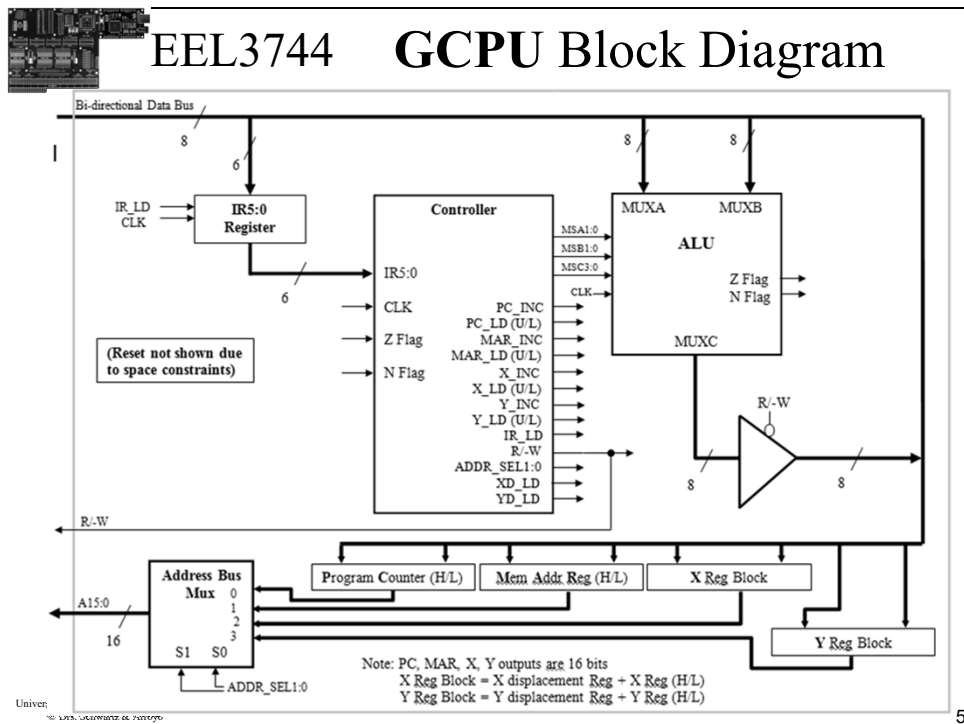


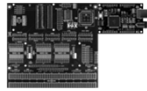
(c) Direct LDAA



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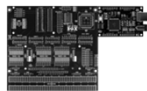
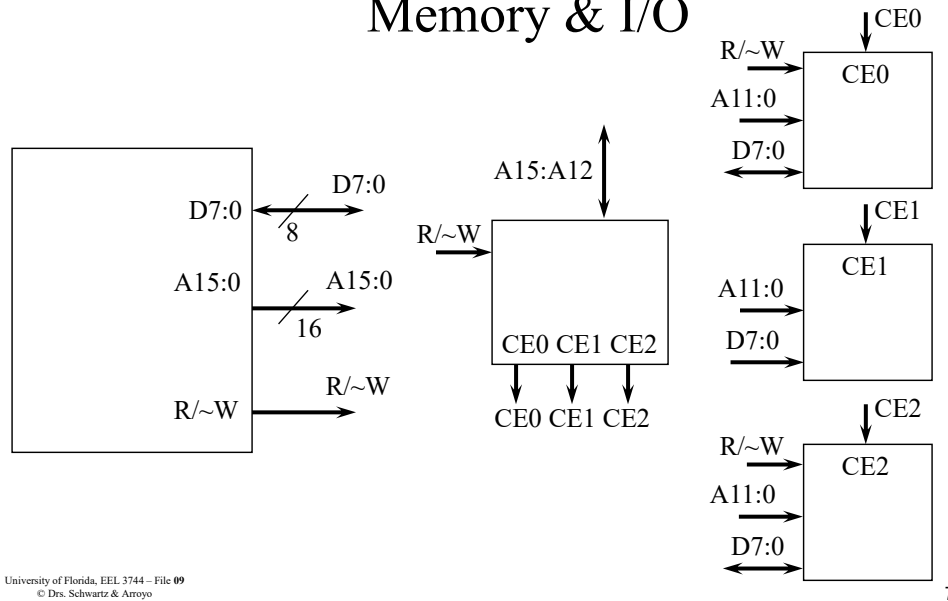
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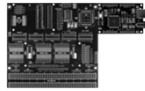
## GCPU with Memory & I/O



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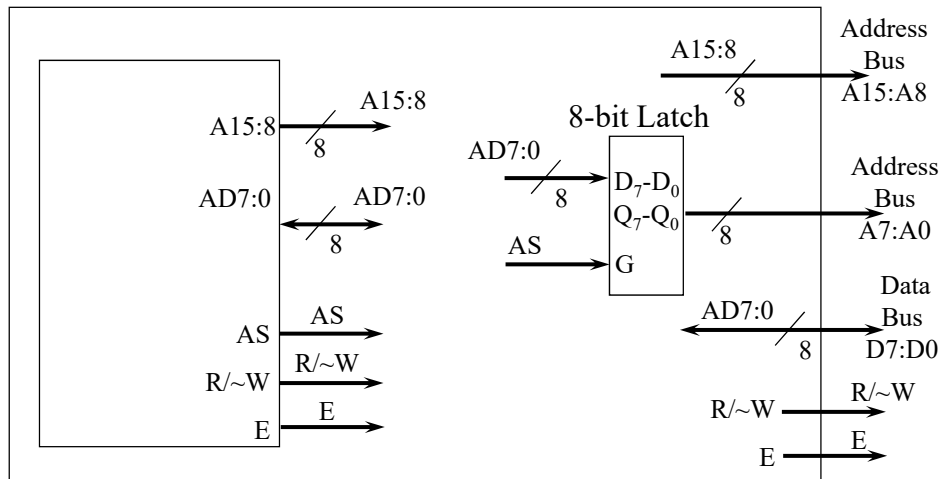
## 6811 Address/Data Buses

- 16-bit address bus
  - > A15-A8
  - > AD7-AD0
- 8-bit data bus
  - > AD7-AD0
- The address/data bus AD7-AD0 is **time-multiplexed**
  - > When AS (address strobe) is true (high), AD7-AD0 are address lines
  - > When the E clock timing signal is high, AD7-AD0 are data lines

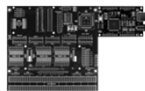


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## 6811 Expanded Mode Implementation

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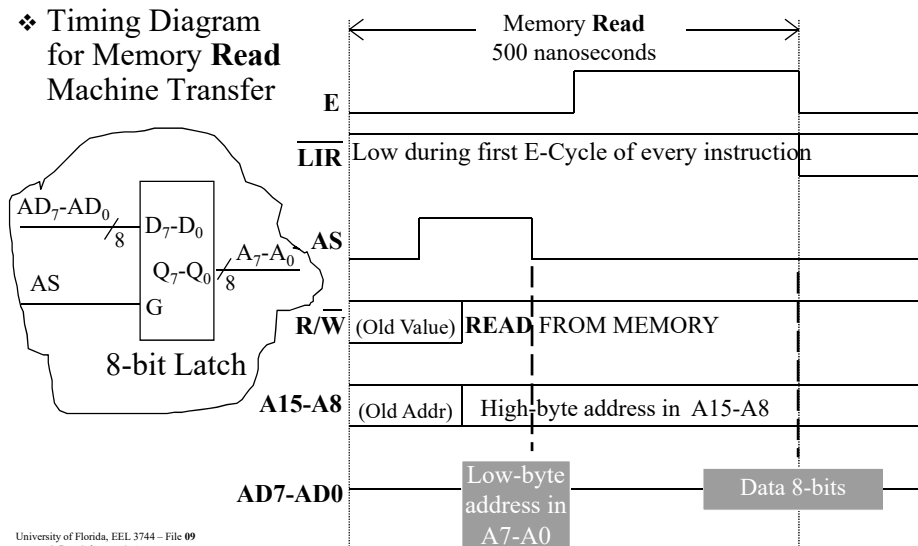
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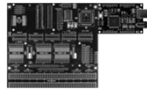
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## 6811 Hardware Interfacing Concepts

❖ Timing Diagram for Memory Read Machine Transfer

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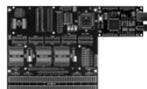


## EEL3744 6811 Steps for Memory Read Operation (describes picture)

1. The high-order 8 bits of the 16-bit address are placed onto  $A_{15}-A_8$  and the low order 8 bits onto  $AD_7-AD_0$ .
2. The signal AS (Address Strobe or Stable) is pulsed during the first half of the corresponding E-cycle. This signal causes the low-order byte of the address to be latched at the **trailing** edge of the AS pulse.
3. With the low-order 8-bits of the address saved in the 8-bit latch, the  $AD_7-AD_0$  lines are now free to be used as a data bus. Therefore, the  $\mu P$  relinquishes control of the data bus so that the memory module can place the subsequently retrieved 8-bit data onto the data bus.
4. At this point the signal  $R/W'$  should be high and remain high for the duration of the E-clock pulse.
5. After an appropriate delay (small enough to guarantee that the data is on the data bus prior to E-clock pulse going from H to L again), the data (or opcode) is available on the data bus (and on  $AD_7-AD_0$ ).
6. The control unit places the data into the appropriate internal register.

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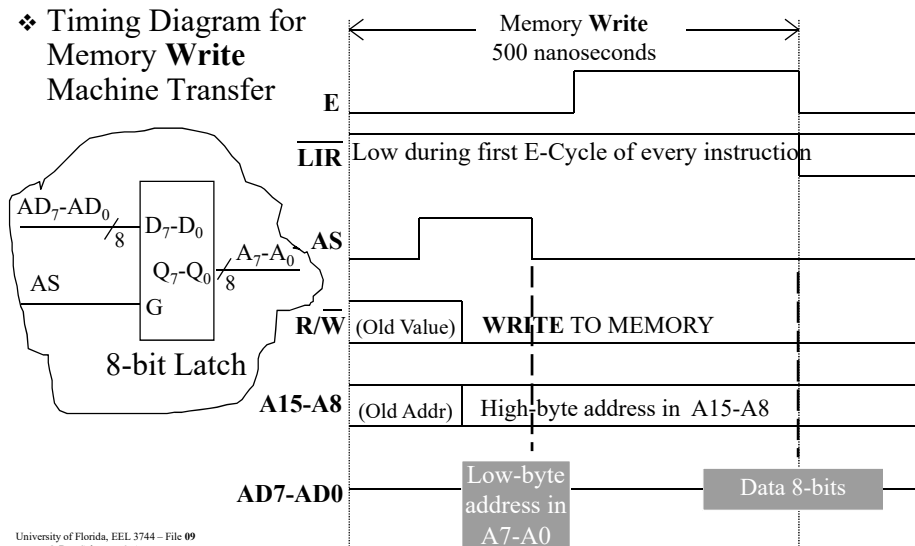
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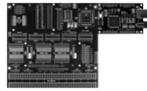
## 6811 Hardware Interfacing Concepts

❖ Timing Diagram for Memory Write Machine Transfer



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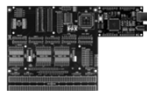


## EEL3744 6811 Steps for Memory Write Operation (describes picture)

1. The high-order 8 bits of the 16-bit address are placed onto  $A_{15}-A_8$  and the low order 8 bits onto  $AD_7-AD_0$ .
2. The signal AS (Address Strobe or Stable) is pulsed during the first half of the corresponding E-cycle, indicating the address/data bus contains the low-order byte of the address. This signal causes the low-order byte of the address to be latched **at the trailing edge** of the AS pulse. Consequently, **the 16-bit address is now available** on the 16-bit address bus.
3. With the low-order 8-bits of the address saved in the 8-bit latch, **the  $AD_7-AD_0$  lines are now free to be used as a data bus**. Therefore, the  $\mu P$  will place the data to be transferred onto the data bus during the second half of the corresponding E-clock pulse.
4. At this point the signal  $R/W'$  should be low and remain low for the duration of the E-clock pulse.

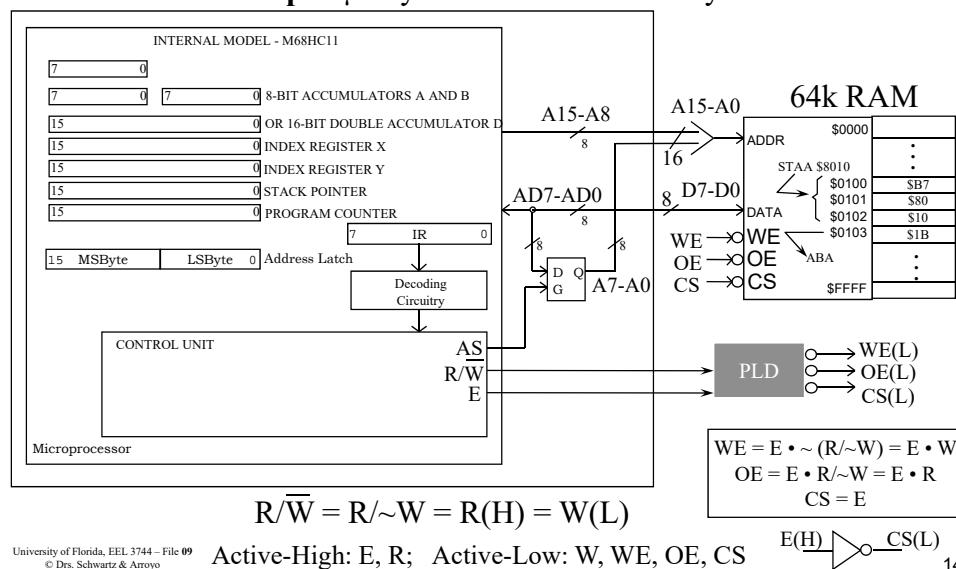
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## EEL3744 6811 Hardware Interfacing Concepts

❖ Example:  $\mu P$  system with 64K memory module

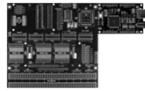


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Active-High: E, R; Active-Low: W, WE, OE, CS

$E(H) \rightarrow CS(L)$

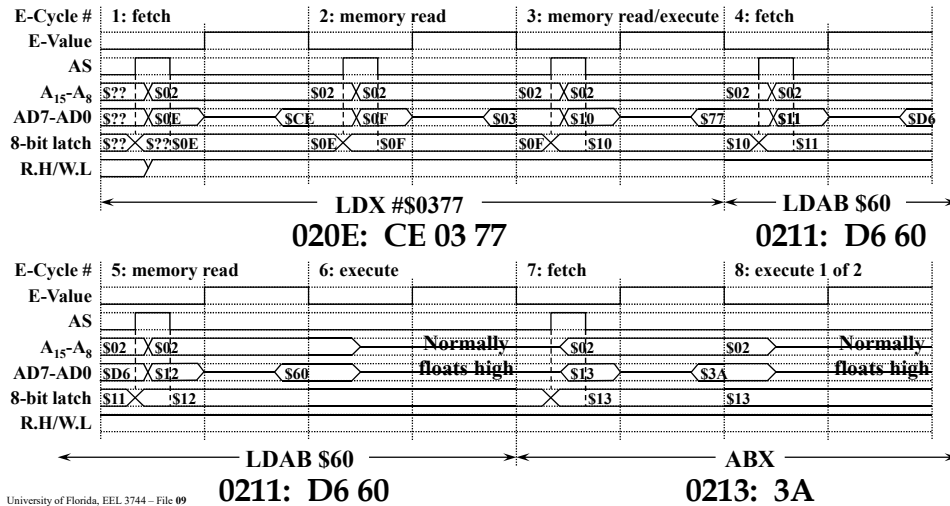
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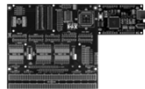
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## 6811 Fetch-Decode-Execute Example

- Suppose we execute the code starting at location \$020E

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## 6811 Fetch-Decode-Execute Example (describes picture)

- Assume that the execution of the instruction in memory location \$036F has just been completed and that the  $\mu P$  is ready to execute the next instruction (**STAA \$8010**), the opcode of which is in memory location \$0370.
- In other words, the  $\mu P$  is ready to begin the fetch-decode-execute cycle for this instruction. At this time, the contents of the PC are \$0370. The following sequence of machine transfers are required to fetch, decode, and execute this instruction.

\$0370 STAA \$8010

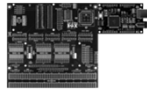
### Machine Cycle 1 (Opcode Fetch)

- The high-order 8 bits, \$03 (%0000 0011), of the PC are placed onto A<sub>15</sub>-A<sub>8</sub>, and the low-order 8 bits, \$70 (%0111 0000), onto AD<sub>7</sub>-AD<sub>0</sub>.
- AS is pulsed, causing \$70 to be latched and become available on A<sub>7</sub>-A<sub>0</sub>.
- The  $\mu P$  relinquishes control of the AD lines.

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## EEL3744 6811 Fetch-Decode-Execute

### Example(describes picture)

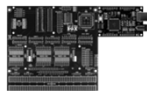
4. The control unit causes R/W' to become high for a read operation.
5. The E-clock pulse goes high. After a delay required by the memory module to output the contents of a memory location, the opcode \$B7 (from location \$0370) is available on the AD<sub>7</sub>-AD<sub>0</sub>. **STAA \$8010**
6. The control unit places the opcode \$B7 into the IR.
7. The instruction is decoded and determined to be an STAA instruction. The control unit “knows” that the address of the destination location is stored in the next two locations in memory following the location containing the STAA opcode. Therefore, two additional memory read machine transfers are required. The PC now contains \$0371.

### Machine Cycle 2 (Memory Read)

1. The high-order 8 bits, \$03 (%0000 0011), of the PC are placed onto A<sub>15</sub>-A<sub>8</sub>, and the low-order 8 bits, \$71 (%0111 0001), onto AD<sub>7</sub>-AD<sub>0</sub>.
2. AS is pulsed, causing \$71 to be latched and become available on A<sub>7</sub>-A<sub>0</sub>.

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## EEL3744 6811 Fetch-Decode-Execute

### Example (describes picture)

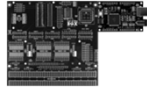
3. The  $\mu$ P relinquishes control of the AD lines. **\$0370 STAA \$8010**
4. The control unit causes R/W' to become high for a read operation.
5. The E-clock pulse goes high. After a delay required by the memory module to output the contents of a memory location, the high-byte \$80 (from location \$0371) is available on the AD<sub>7</sub>-AD<sub>0</sub>.
6. The control unit places the \$80 into the **high-order** byte of a 16-bit temporary effective address register. The PC is incremented.

### Machine Cycle 3 (Memory Read)

The operations for this memory read machine transfer are similar to those of Machine Transfer 2. The only difference is that the contents of memory location \$0372 are retrieved and stored in the **low-order** byte of the temporary effective address register, thereby completing the 16-bit destination address (\$8010) of the STAA instruction. The PC is incremented.

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## 6811 Fetch-Decode-Execute

### Example (describes picture)

#### Machine Cycle 4 (Memory Write)

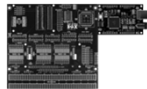
STAA \$8010

1. The high-order 8 bits, \$80 (%1000 0000), of the temporary effective address register are placed onto A<sub>15</sub>-A<sub>8</sub>, and the low-order 8 bits, \$10 (%0001 0000), onto AD<sub>7</sub>-AD<sub>0</sub>.
2. AS is pulsed, causing \$10 to be latched and become available on A<sub>7</sub>-A<sub>0</sub>.
3. The contents (\$57) of Register A are placed onto AD<sub>7</sub>-AD<sub>0</sub>, thereby making them available on D<sub>7</sub>-D<sub>0</sub>.
4. The control unit causes R/W' to become low for a write operation.
5. After a delay required by the memory module to place data into a memory location, the contents of memory location \$8010 are changed to \$57, thereby completing the memory write machine transfer and the execution of the STAA instruction.



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## 6811 Fetch-Decode-Execute

### Example (describes picture)

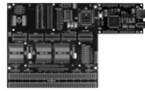
- Below is the program (list file) from which the previous example was extracted

Mach\_cyc.lst

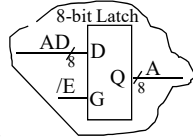
0001	0060	ORG	\$0060
0002	0060 01	DC.B	\$01
0003			
0004	0377	ORG	\$0377
0005	0377 8e 04 88	LDS	#\$0488
0006			
0007	020e	ORG	\$20E
0008	020e ce 03 77	MAIN:	LDX #\$0377
0009	0211 d6 60		LDAB \$60
0010	0213 3a		ABX
0011	0214 a6 01		LDAA 1,X
0012	0216 20 fe	HERE:	BRA HERE

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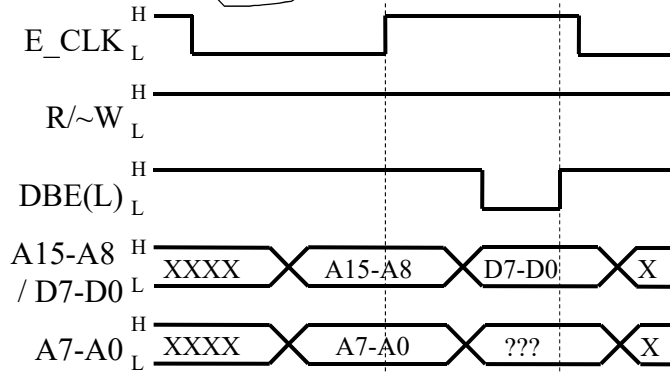
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## EEL3744 68HC12 Expanded Narrow-Mode Read Timing



See M68HC12B/D, section 19.16 for more info



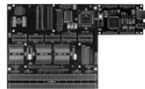
Above is for a 4MHz oscillator  $\Rightarrow$   
 $f_{E\_CLK} = 2\text{MHz}$  and  $T_{E\_CLK} = 500\text{ns}$

Q: When do you read?  
 A:  $DBE * R * f(\text{Addr})$

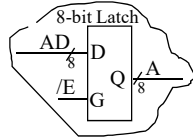
1. Addr setup time from  $E\_CLK$  rise: 94ns (min)
2. Addr hold time  $E\_CLK$  rise: 107ns (min)
3. Data setup from ECLK fall: 25ns (min)
4. Data hold time from  $E\_CLK$  fall: 0ns (no need)
5. DBE delay time from  $E\_CLK$  rise: 133ns (max)
6. DBE valid: 115ns (min)
7. DBE hold time to  $E\_CLK$  fall: -10ns to 3ns

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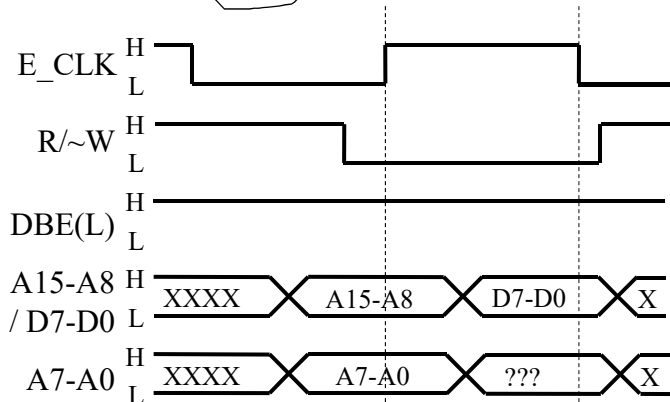
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## EEL3744 68HC12 Expanded Narrow-Mode Write Timing



See M68HC12B/D, section 19.16 for more info



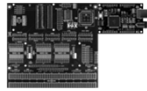
Above is for a 4MHz oscillator  $\Rightarrow$   
 $f_{E\_CLK} = 2\text{MHz}$  and  $T_{E\_CLK} = 500\text{ns}$

1. Addr setup time from  $E\_CLK$  rise: 94ns (min)
2. Addr hold time  $E\_CLK$  rise: 107ns (min)
3. Data setup from ECLK fall: 83ns (min)
4. Data hold time from  $E\_CLK$  fall: 20ns (min)

Q: When do you write?  
 A:  $W * E * f(\text{Addr})$

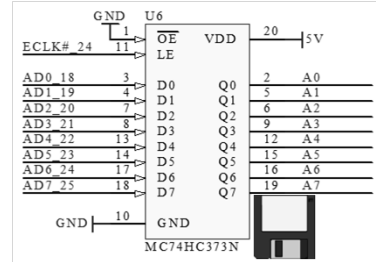
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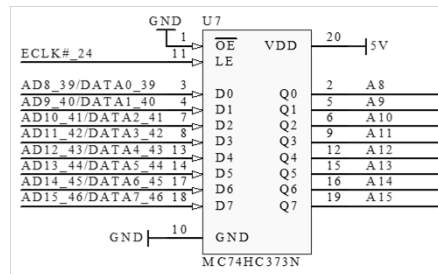


## EEL3744 Latching the 68HC12 Address (Expanded Narrow-Mode)

- The AD15:AD8 pins of **Port A** are used for both A15:A8 (high 8-bits of the address) and D7:D0 (8-bit data)
  - AD15:AD8 are also known as D7:D0, although they function only as D7:D0 at specific times (see timing diagrams)
- The AD7:AD0 pins of **Port B** are used for A7:A0 (low 8-bits of the address) and **not** for data (in expanded narrow-mode)
- The 74'373 on PortB (AD7-0) is **not** needed, in theory
  - But it **might** be needed in practice. This can be tested with an LSA.

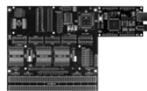


6812\_Board\_Manual



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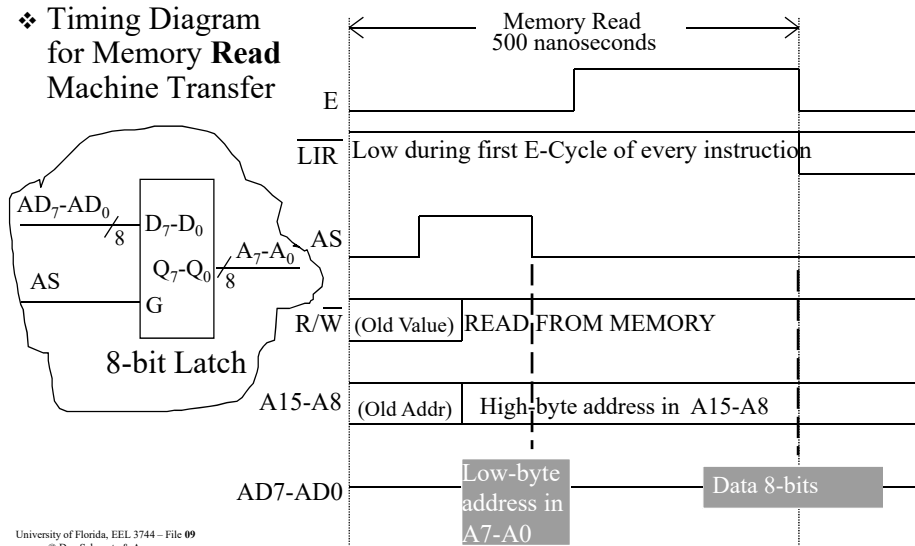
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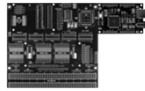
### 68HC11 Expanded Mode Read Timing

- ❖ Timing Diagram for Memory Read Machine Transfer



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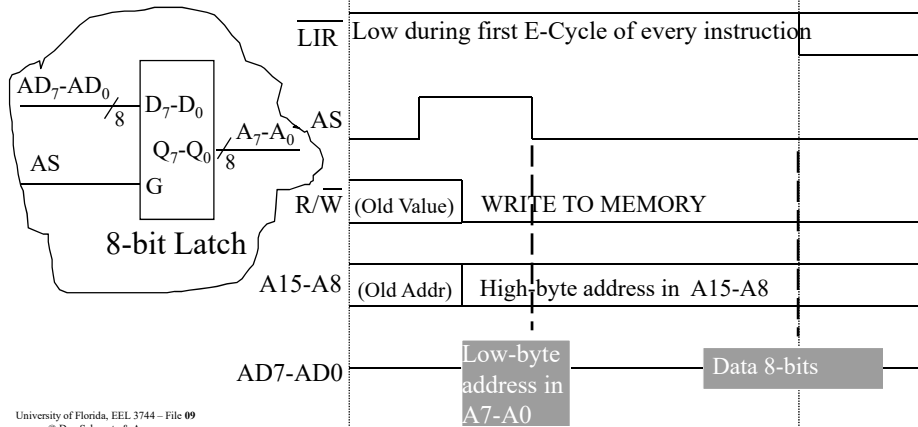
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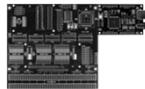
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## 68HC11 Expanded Mode Write Timing

❖ Timing Diagram for Memory Write Machine Transfer



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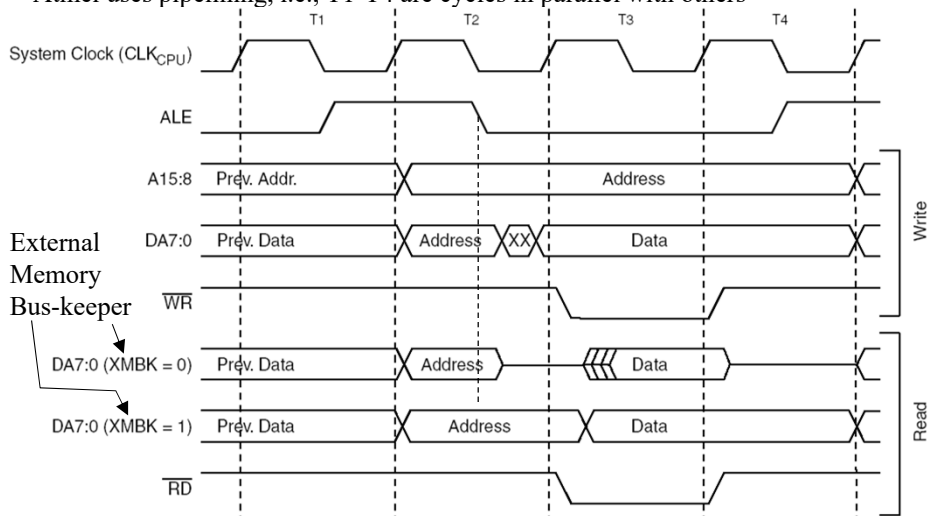
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## Atmel AVR Mega8515L External Memory R/W Timing

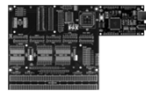
- Need same latch as 68HC11 (Atmel's ALE = 68HC12's AS)
- Atmel's CLK is inverse of Motorola's E-clock
- Atmel uses pipelining, i.e., T1-T4 are cycles in parallel with others



Atmel\_Mega8515L.pdf

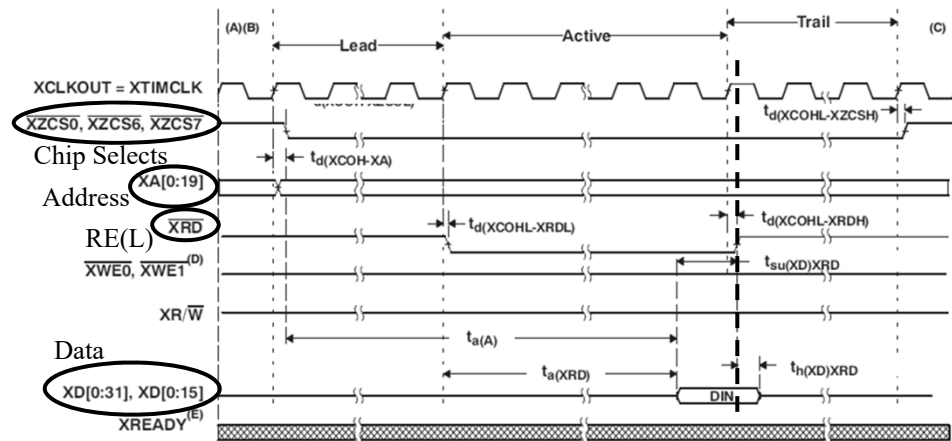


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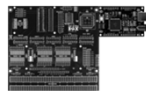
TMS320F2833x  
Data Manual.pdf

## EEL3744 DSC F2833 Generic Read Timing (Figure 6-23, TMS320F2833x Data Manual)



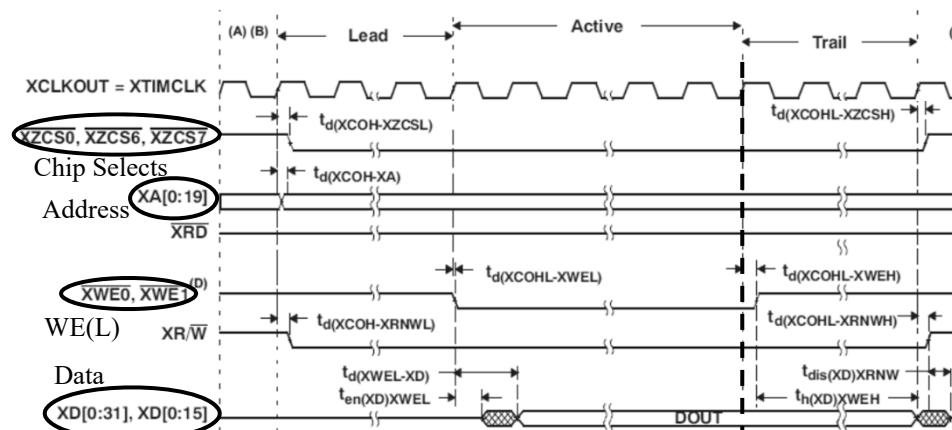
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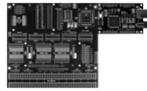
TMS320F2833x  
Data Manual.pdf

## EEL3744 DSC F2833 Generic Write Timing (Figure 6-24, TMS320F2833x Data Manual)



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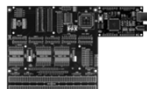


## EEL3744 XMEGA Write followed by Read and Pipeline

- Be careful when having a **write followed by a read access**
  - > This has been documented to occur with the keypad when a read immediately follows a write
    - If you can find documentation of this in the Atmel manuals, please tell me where you found it!
  - > **If this does occur**, add a **NOP** assembly instructions between a write and read instructions
    - If one NOP does not work, add 2; if 2 does not work, add 3
      - For the XMEGA, one NOP should work
      - If you need more than one NOP, let me know!

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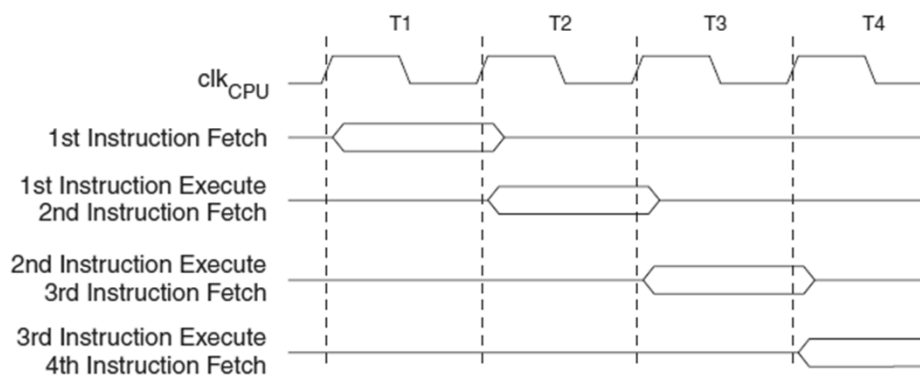
29



## EEL3744 XMEGA Pipeline: Execution Timing

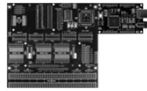
- The parallel instruction fetches and instruction executions timing

See doc8331,  
Figure 3-2



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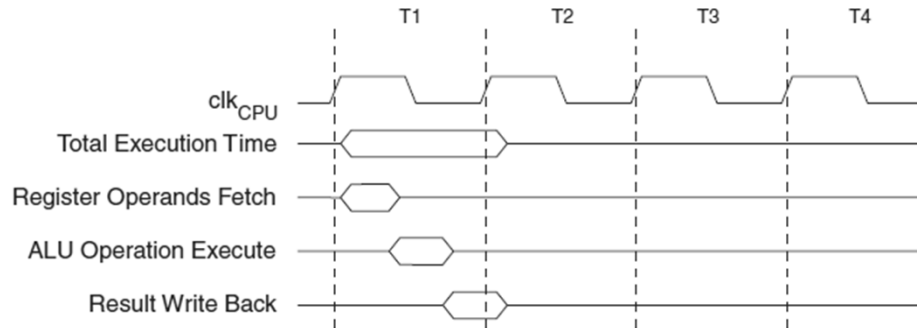


EEL3744

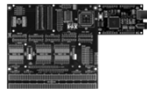
See doc8331,  
Figure 3-3

## XMEGA Pipeline: Execution Timing

- Single cycle ALU instruction
  - > In a single clock cycle, an ALU operation using two register operands is executed and the result is stored back to the destination register

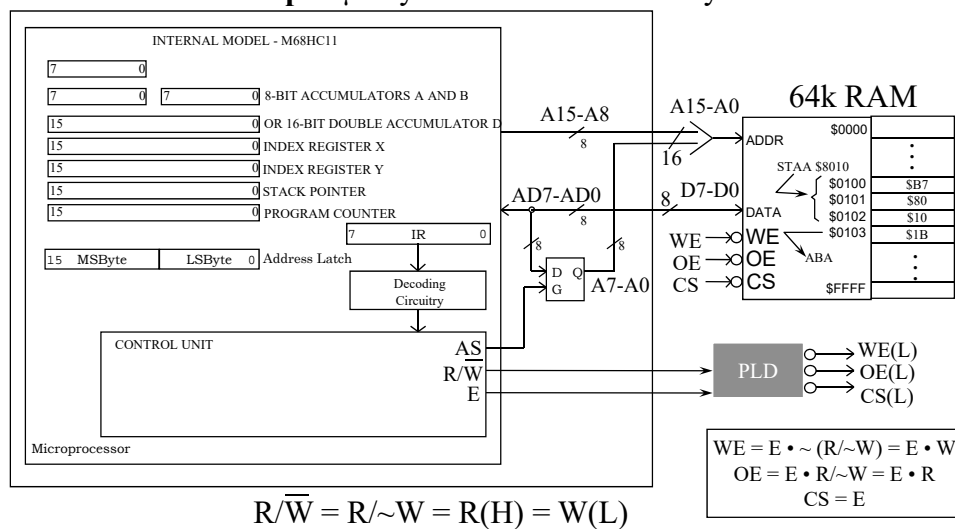
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## 6811 Hardware Interfacing Concepts

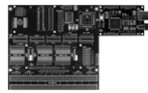
❖ Example:  $\mu$ P system with 64K memory moduleUniversity of Florida, EEL 3744 – File 09  
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Active-High: E, R; Active-Low: W, WE, OE, CS

E(H)  $\rightarrow$  CS(L)

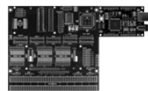
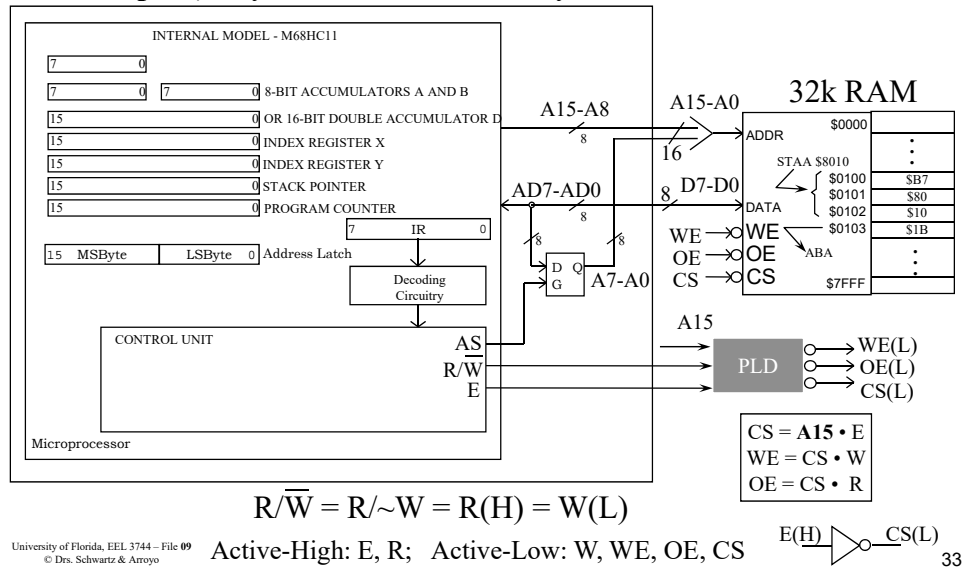
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## EEL3744 6811 Hardware Interfacing Concepts (w/ Addr Decoding)

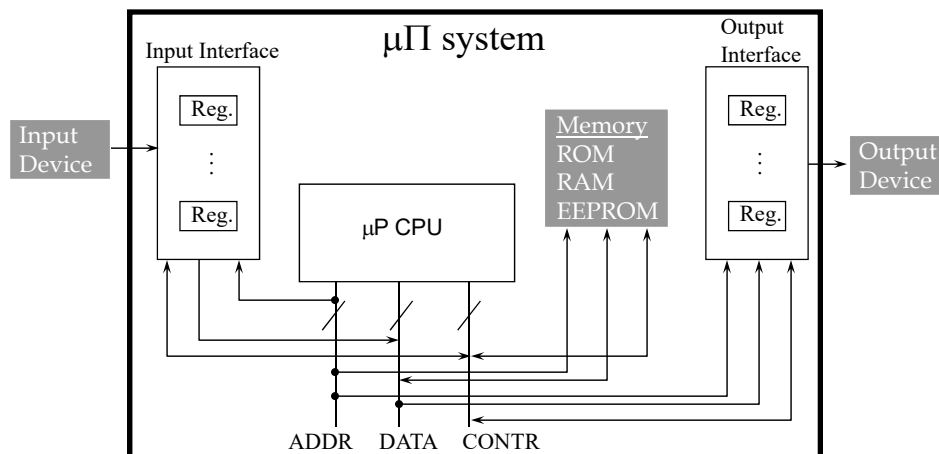
❖ Example:  $\mu$ P system with 32K memory module at \$8000-\$FFFF

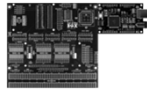


## EEL3744

### Hardware/Interfacing Review

- Block Diagram of a Basic Microprocessor System





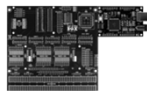
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## 68HC12 Interfacing Signals/Pins

- A 16-bit Address Bus  $A_{15}-A_0$ 
  - >  $A_{15}-A_8$  are available through  $PA_7-PA_0$  in Expanded Mode
  - >  $A_7-A_0$  are available through  $PB_7-PB_0$  in Expanded Mode
  - > Address pins valid when E-clock is rising
- An 8-bit Data Bus  $D_7-D_0$ 
  - >  $D_7-D_0$  through  $PA_7-PA_0$  in Expanded Narrow Mode when  $E=1$
- A 4-bit Control Bus  $E, DBE, R/\sim W, \text{Reset}$ 
  - >  $PE_2$  becomes  $R/\sim W$  in Expanded Mode
  - >  $PE_7$  becomes  $DBE$  (active-low data bus enable) in Expanded Mode
  - >  $PE_4$  becomes  $E$  (event clock) in Expanded mode
    - For 4MHz oscillator,  $E=2\text{ MHz}$ ; i.e.,  $500\text{ns}=0.5\mu\text{s}$  Event Clk
  - > **Reset** (active-low) is always available
    - Needed to protect external devices from corruption during the reset operation

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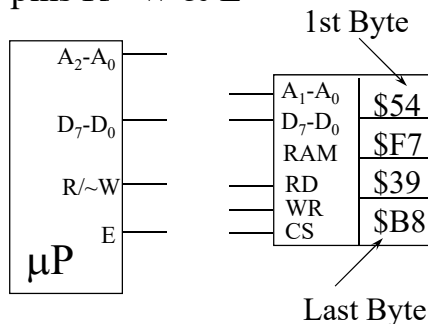


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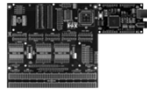
## 68HC11

### Hardware/Interfacing

- Example R1: Add a 4×8 bit (4-bytes) RAM module to a hypothetical  $\mu\text{P}$  with 3 address pins, 8 data pins and control pins  $R/\sim W$  &  $E$
- $D_7-D_0$  on the  $\mu\text{P}$  connect to  $D_7-D_0$  on the RAM
- $RD = E \bullet R/\sim W$
- $WR = E \bullet (R/\sim W)'$
- Two of the three address lines go to  $A_1-A_0$  on the RAM;  $CS = A_i$

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68HC11

## Hardware/Interfacing

- What are the consequences of these choices?
  - > Choice 1:  $CS=A_2$ ;  $A1=A_1$ ;  $A0=A_0$ 
    - When the  $\mu P$  issues address 000; the RAM does not respond since  $CS=A_2=0$ ; similarly for addresses 001, 010, 011
    - For address 100 the  $\mu P$  reads \$54, for 101 the  $\mu P$  reads \$F7, for 110 the  $\mu P$  reads \$39, for 111 the  $\mu P$  reads \$B8
    - The 4-byte RAM starts at address 100

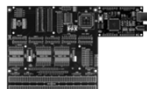
$A_1-A_0$	\$54
$D_7-D_0$	\$F7
RD	\$39
WR	\$B8
CS	

1.  $CS=A_2$ ;  $A1=A_1$ ;  $A0=A_0$
2.  $CS=/A_2$ ;  $A1=A_1$ ;  $A0=A_0$
3.  $CS=A_1$ ;  $A1=A_2$ ;  $A0=A_0$
4.  $CS=A_0$ ;  $A1=A_2$ ;  $A0=A_1$

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Addr	Choice 1	Choice 2	Choice 3	Choice 4
000	None	\$54	None	None
001	None	\$F7	None	\$54
010	None	\$39	\$54	None
011	None	\$B8	\$F7	\$F7
100	\$54	None	None	None
101	\$F7	None	None	\$39
110	\$39	None	\$39	None
111	\$B8	None	\$B8	\$B8

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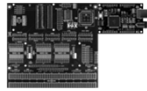
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## Conclusions from Example R1

- The data in the RAM will not be accessed contiguously unless we connect the matching contiguous low order lines to the RAM, i.e.,  $A1=A_1$  and  $A0=A_0$
- We have a choice of  $CS=/A_2$  or  $CS=A_2$ 
  - > If want the RAM in the “**low memory range**,” choose  $CS=/A_2$
  - > If want the RAM in the “**high memory range**,” choose  $CS=A_2$
- For **contiguous access** we always connect the **low order** address pins to **all** the RAM address pins
- $CS = f(\text{unused high order address lines})$ . If we have  $m$  unused address lines we will have  $2^m$  possible starting addresses for the contiguous memory block

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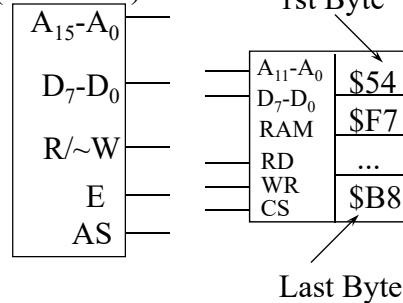
68HC11

## Hardware/Interfacing

- **Example R2:** Add a 4k×8 bit (4k-bytes, 4K) RAM module to the M68HC11

68HC11

(with latch)



- D<sub>7</sub>-D<sub>0</sub> on the μP connect to D<sub>7</sub>-D<sub>0</sub> on the RAM

- RD = E • R/~W

- WR = E • (R/~W)'

- μP A<sub>11</sub>-A<sub>0</sub> to A<sub>11</sub>-A<sub>0</sub> on the RAM; CS=f(A<sub>15</sub>-A<sub>12</sub>)

$$1. CS = /A_{15} \bullet /A_{14} \bullet /A_{13} \bullet /A_{12}$$

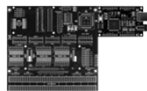
$$2. CS = /A_{15} \bullet /A_{14} \bullet /A_{13} \bullet A_{12}$$

$$3. CS = /A_{15} \bullet /A_{14} \bullet A_{13} \bullet /A_{12}$$

$$4. CS = /A_{15} \bullet /A_{14} \bullet A_{13} \bullet A_{12}$$

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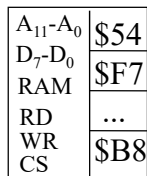
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## 68HC11 Hardware/Interfacing Review

- What are the consequences of these choices?

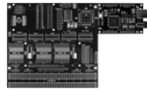
> Choice 1: CS = /A<sub>15</sub> • /A<sub>14</sub> • /A<sub>13</sub> • /A<sub>12</sub>

- When the μP issues address 0000 xxxx xxxx xxxx; the RAM responds since CS=1•1•1•1 (address lines are active-high)
- For address 0000 0000 0000 0000 the μP reads \$54, for \$0001 the μP reads \$F7, for \$0FFF the μP reads \$B8
- The 4K-byte RAM starts at address \$0000

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Address	C1	C2	C3	C4
0000 0000 0000 0000	\$54	None	None	None
0000 0000 0000 0001	\$F7	None	None	None
0001 0000 0000 0000	None	\$54	None	None
0001 0000 0000 0001	None	\$F7	None	None
0010 0000 0000 0000	None	None	\$54	None
0010 0000 0000 0001	None	None	\$F7	None
0011 0000 0000 0000	None	None	None	\$54
0011 0000 0000 0001	None	None	None	\$F7

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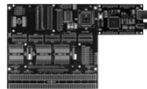
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## 68HC11 Conclusions from Example R2

- For choice 1,  $CS = \overline{A_{15}} \bullet \overline{A_{14}} \bullet \overline{A_{13}} \bullet \overline{A_{12}}$  the 4K memory block begins at address \$0000; the range is \$0000-\$0FFF
- For choice 2,  $CS = \overline{A_{15}} \bullet \overline{A_{14}} \bullet \overline{A_{13}} \bullet A_{12}$  the 4K memory block begins at address \$1000; the range is \$1000-\$1FFF
- For choice 3,  $CS = \overline{A_{15}} \bullet \overline{A_{14}} \bullet A_{13} \bullet \overline{A_{12}}$  the 4K memory block begins at address \$2000; the range is \$2000-\$2FFF
- For choice 4,  $CS = \overline{A_{15}} \bullet \overline{A_{14}} \bullet A_{13} \bullet A_{12}$  the 4K memory block begins at address \$3000; the range is \$3000-\$3FFF
- There are  $2^4=16$  choices for a starting address for the 4K block, mainly, \$0000, \$1000, \$2000,..., \$E000, \$F000

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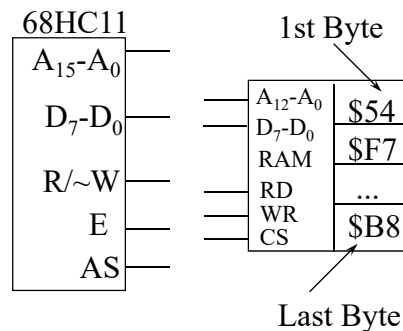


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68HC11

## Hardware/Interfacing

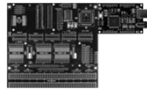
- Example R3: Add a 8k×8 bit (8k-bytes, 8K) RAM module to the M68HC11 starting at address \$4000



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- D<sub>7</sub>-D<sub>0</sub> on the  $\mu P$  connect to D<sub>7</sub>-D<sub>0</sub> on the RAM
- $RD = E \bullet R/\sim W$
- $WR = E \bullet (R/\sim W)'$
- $\mu P$  A<sub>12</sub>-A<sub>0</sub> to A<sub>12</sub>-A<sub>0</sub> on the RAM;  $CS = f(A_{15}-A_{13})$
- Since starting address is **0100 0000 0000 0000** the only choice is  $CS = \overline{A_{15}} \bullet \overline{A_{14}} \bullet \overline{A_{13}}$
- The address range is \$4000-\$5FFF

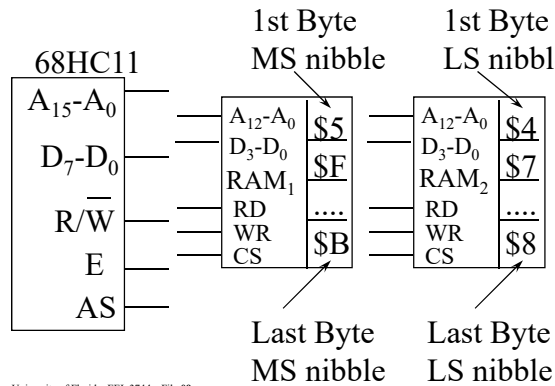


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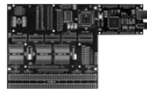
## Hardware/Interfacing

- **Example R4:** Add a 8K of RAM using two 8k x 4 RAM chips to the M68HC11 starting at address \$A000

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- D<sub>3</sub>-D<sub>0</sub> on the  $\mu$ P to D<sub>3</sub>-D<sub>0</sub> on RAM<sub>2</sub> (LS nibble)
- D<sub>7</sub>-D<sub>4</sub> on the  $\mu$ P to D<sub>3</sub>-D<sub>0</sub> on RAM<sub>1</sub> (MS nibble)
- WR = E • (R/~W)'
- RD = E • R/~W
- $\mu$ P A<sub>12</sub>-A<sub>0</sub> to A<sub>12</sub>-A<sub>0</sub> on the RAM; CS= $f(A_{15}-A_{13})$
- For starting address 1010 0000 0000 0000 the only choice is CS=A<sub>15</sub>•A<sub>14</sub>•A<sub>13</sub>
- The address range is \$A000-\$BFFF

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68HC11 Memory Map  
(with BUFFALO)

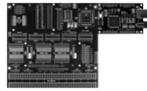
- ❖ Let us draw a memory map for the M68HC11E9 EVBU Board

START	END	TYPE
\$0000	\$01FF	RAM
\$0200	\$0FFF	{EMPTY}
\$1000	\$103F	Internal Registers
\$1040	\$B5FF	{EMPTY}
\$B600	\$B7FF	EEPROM
\$B800	\$CFFF	{EMPTY}
\$D000	\$FFFF	ROM {BUFFALO}

- ❖ We can place additional 4K memory modules at address \$2000, \$3000, \$4000, \$5000, \$6000, \$7000, \$8000, \$9000, \$A000, \$C000

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## 68HC12 Memory Map (with UF68HC12 Board)

- Available Memory:  $2^{16} = 64K$ 
  - >0000 0000 0000 0000 to 1111 1111 1111 1111
  - >\$0000 to \$FFFF

- On chip:

- >Regs: \$0000 to \$01FF
- >RAM: \$0800 to \$0BFF
- >EEPROM: \$0D00 to \$0FFF

NOTICE: The first two hex digits discriminates between types

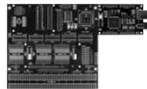
- On UF68HC12 Board (off-chip):

- >E(E)PROM (D-Bug4744): \$E000 to \$FFFF
- >68HC12 Interrupt Vectors: \$FFC0 to \$FFFF

NOTICE: Bit A15 is all that is needed to pick EPROM

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## 68HC12 Memory Map (with UF68HC12 Board)

❖ Memory map for the UF68HC12 Board

START	END	TYPE
\$0000	\$01FF	Regs
\$0200	\$07FF	{EMPTY}
\$0800	\$0BFF	1KB Internal RAM
\$0800	\$08FF	RAM, <b>D-Bug4744</b> pseudo-vectors
\$0900	\$0BFF	User RAM (~\$890-\$8FF may be available)
\$0C00	\$0CFF	{EMPTY}
\$0D00	\$0FFF	768 bytes Internal EEPROM
\$1000	\$DFFF	{EMPTY}
\$E000	\$FFFF	8KB External EPROM { <b>D-Bug4744</b> }
\$FFC0	\$FFFF	Vectors in EPROM

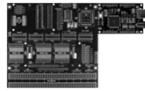
D-Bug4744 uses only some of this range, probably \$800 to about \$088F.

If interrupts not used, \$800-\$8FF is available.

❖ We can place additional 4K memory modules at address \$1000, \$2000, ..., \$7000, \$8000, ..., \$C000, \$D000

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See also Fig 5.6 in the M68HC12B/D



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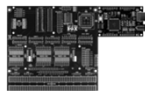
## XMEGA Data Memory Map

See doc8385,  
Figure 7-2  
CORRECTED

Addr (hex)	Description
0 – 0FFF	I/O Registers (4kB) [0 – BC3 on ours]
1000 – 17FF	EEPROM (2kB)
1800 – 1FFF	Reserved
2000 – 3FFF	Internal SRAM (8kB)
4000 – FF FFFF	External “Memory” (0 to ~16MB)

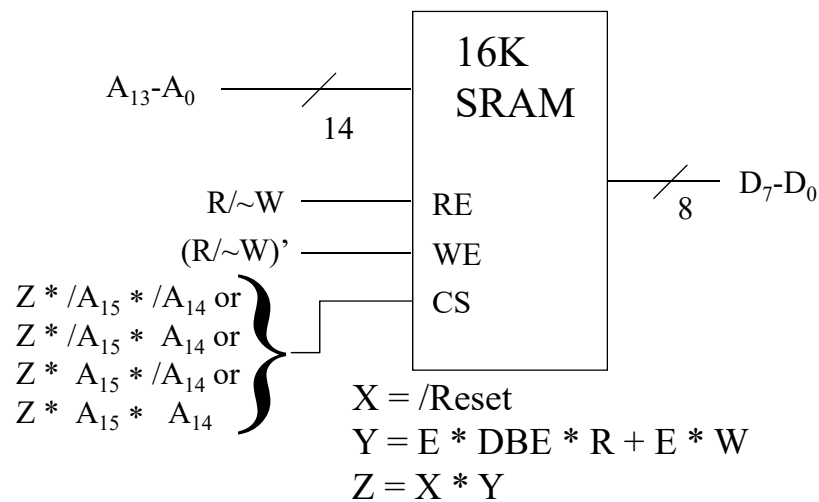
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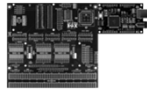
## 68HC12 16KB Memory Expansion



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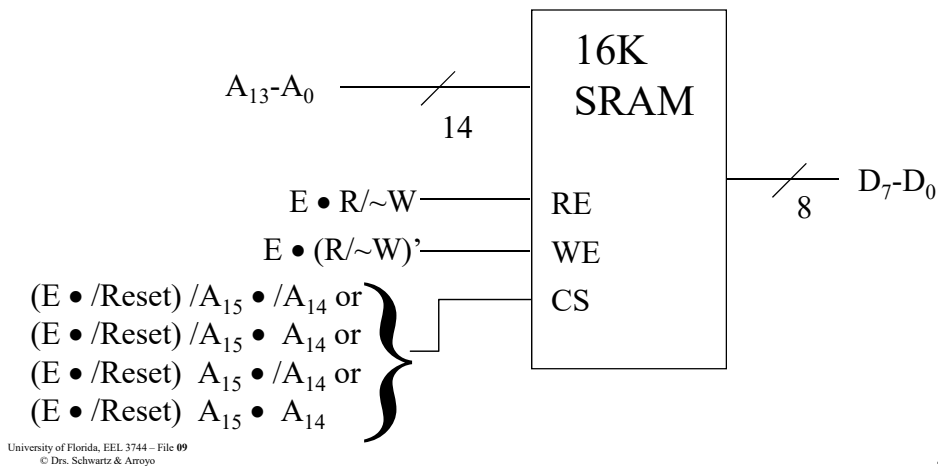
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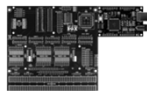


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## 68HC11 16KB Memory Expansion

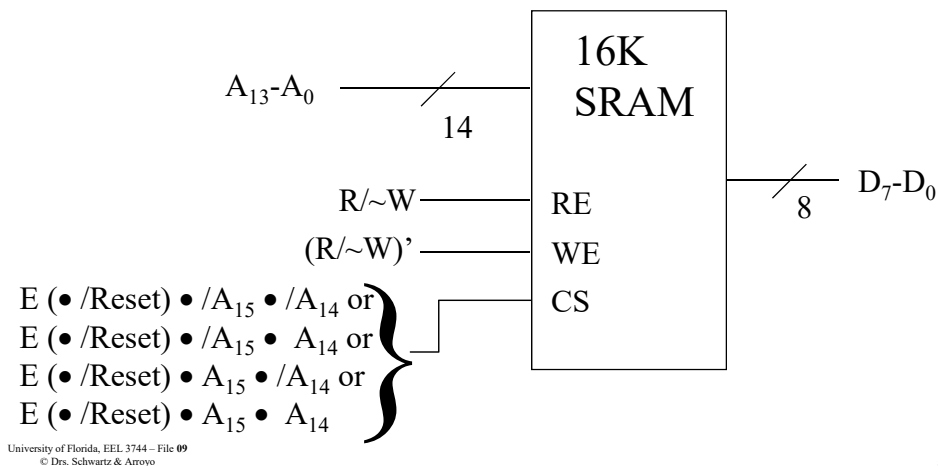


49

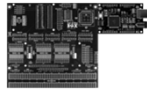


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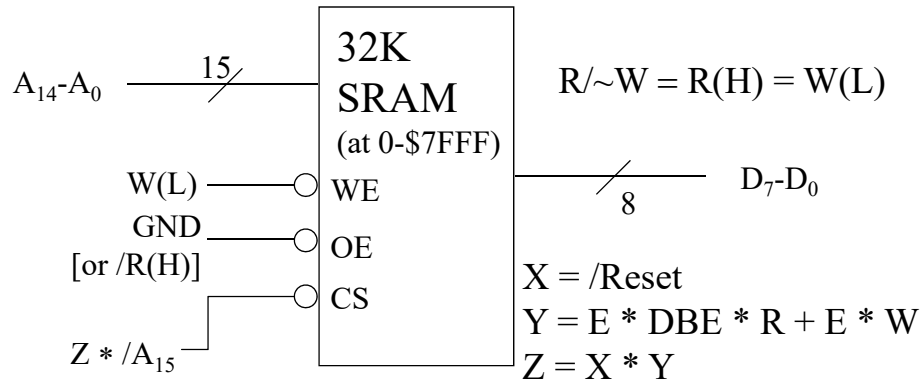
## 68HC11 16KB Memory Expansion



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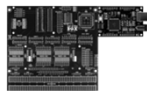
## EEL3744 68HC12 32KB Memory Expansion



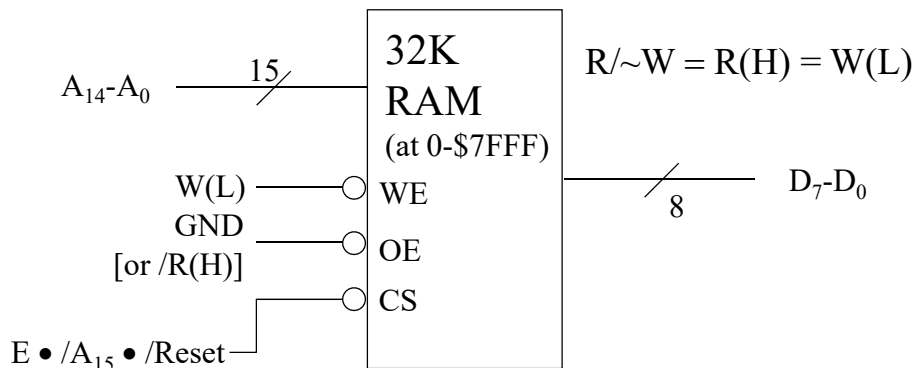
- The output buffer is automatically disabled whenever WE is asserted, even if OE asserted
- I.e., WE has priority over OE.

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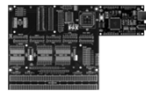
## EEL3744 68HC11 32KB Memory Expansion



- The output buffer is automatically disabled whenever WE is asserted, even if OE asserted
- I.e., WE has priority over OE.

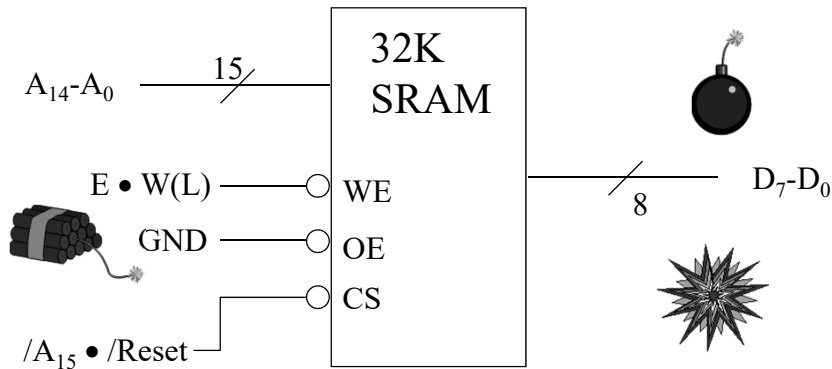
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## 68HC11 Expansion Data Collision

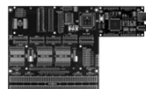


Do NOT do this. Data collision when E is low, i.e., HC11 AD<sub>7-0</sub> and RAM D<sub>7-0</sub> both output data on the same bus!!!

Can you come up with a similar scenario for the HC12?

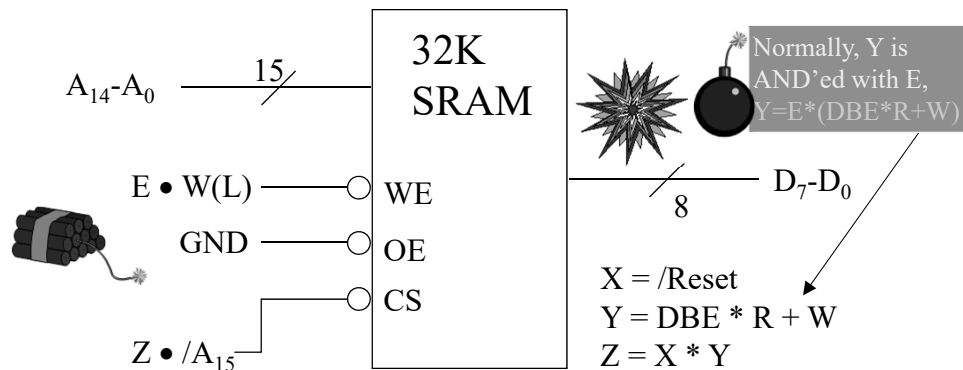
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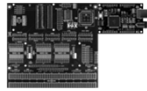
## 68HC12 Expansion Data Collision



Do NOT do this. Data collision when E is low (and W is true), i.e., HC12's AD<sub>15-8</sub> and RAM D<sub>7-0</sub> both output data on the same bus at the same time!!!

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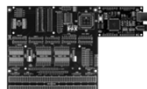
## EEL3744 68HC11 Interfacing the Memory Module

- ❖ Since there is already **some** on-board RAM, ROM and EEPROM in a M68HC11 system, external memory modules are often much smaller than 64K bytes, and so require fewer than 16 address bits.
- ❖ **[Example]** A  $\mu$ P system configuration with a **2K** external memory module starting at Memory Location **\$4000** (through \$47FF since  $2k=2^{11}$ ).
- ❖ **<Method 1> A Fully Decoded System**
- ❖ The first location of the 2K module: \$4000 (%0100 0000 0000 0000)
- ❖ The last location of the 2K module: \$47FF (%0100 0111 1111 1111)
- ❖ Hence, the first 5-bit of address (%01000 above) can be used for CS (chip select) as follows:

$$CS = E \cdot /A_{15} \cdot A_{14} \cdot /A_{13} \cdot /A_{12} \cdot /A_{11}$$

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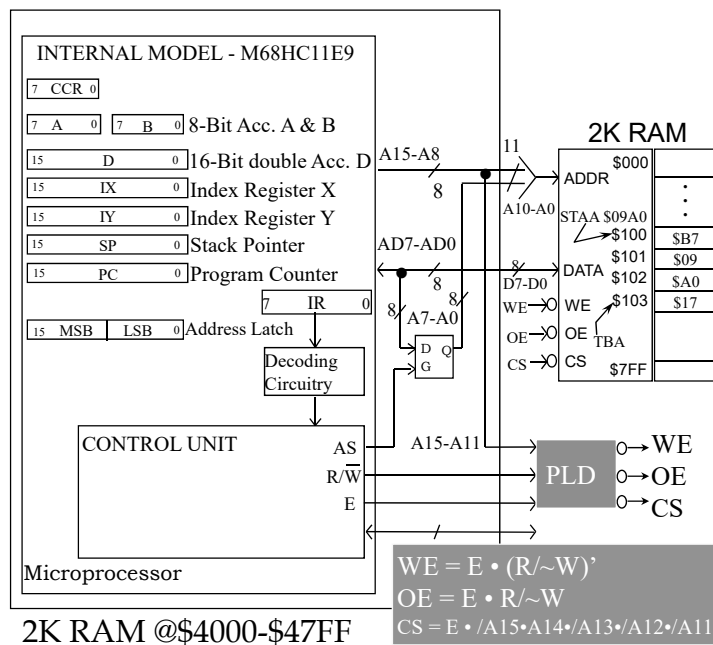


## EEL3744 68HC11 Fully Decoded Expansion

Fully Decoded System w/ 2K Memory Module

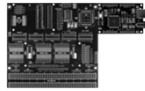
### Memory Map

\$0000	512-byte RAM
\$01FF	
	⋮
\$4000	2K-byte RAM
\$47FF	
	⋮
\$B600	512-byte EEPROM
\$B7FF	
	⋮
\$D000	12K-byte ROM
\$FFFF	



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## Partial Address Decoding

### <Method 2> A Partially Decoded System using the first 2-bits

- ❖ Unlike in the fully decoded system, three of the five high address bits, mainly  $A_{13}$ ,  $A_{12}$ , and  $A_{11}$  are left **unconnected** and so are **not** used to select a memory location in the memory module. Consequently, these **3 bits** of the address are effectively **don't cares**. As a result, each location in the 2K-byte external memory module has  $2^3 = 8$  **different** addresses or **aliases** as follows:

%0100 0000 0000 0000 ~ %0100 0111 1111 1111 (\$4000 - \$47FF)

%0100 1000 0000 0000 ~ %0100 1111 1111 1111 (\$4800 - \$4FFF)

%0101 0000 0000 0000 ~ %0101 0111 1111 1111 (\$5000 - \$57FF)

⋮

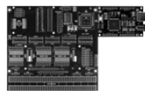
%0111 1000 0000 0000 ~ %0111 1111 1111 1111 (\$7800 - \$7FFF)

- ❖ Hence, the first 2-bit of address (%01) can be used for CS (chip select) as follows:  $CS = E \cdot /A_{15} \cdot A_{14}$

%01-- -000 0000 0000 ~ %01-- -1111 1111 1111 (start - end)

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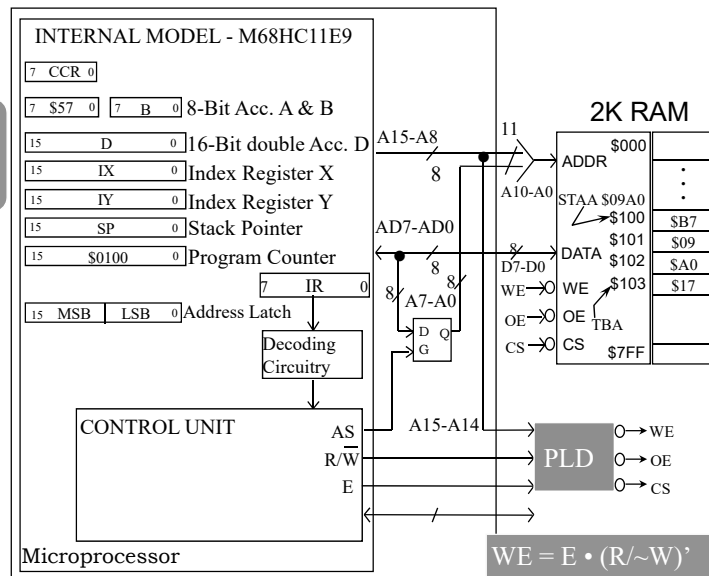


EEL3744

Partially Decoded  
System w/ 2K  
Memory Module

#### Memory Map

\$0000	512-byte RAM
\$01FF	⋮
\$4000	2K-byte RAM
\$7FFF	Repeated 8 Times
\$B600	⋮
\$B7FF	512-byte EEPROM
\$D000	⋮
\$FFFF	12K-byte ROM

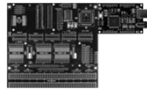


2K RAM @ \$4000-\$47FF or \$4800-\$4FFF ... or  
\$7000-\$77FF or \$7800-\$7FFF

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$WE = E \cdot (R/\sim W)'$   
 $OE = E \cdot R/\sim W$   
 $CS = E \cdot /A_{15} \cdot A_{14}$

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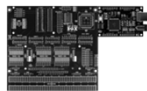
EEL3744

## Partial -vs- Full Address Decoding

- ❖ A partially decoded system has the advantage of being simple and inexpensive since fewer circuitry is required. However, it has the disadvantage that since each memory location has more than one address, care must be taken to ensure that the addresses are referenced in some systematic manner in the software programs. Otherwise, difficulties may arise in the maintenance of the software and hardware of the  $\mu$ P system. For example, it may be difficult to expand the memory module at some later date.
- ❖ This is not a problem for a fully decoded system, which has the advantage that each memory location has just one address. However, a fully decoded system has the disadvantage of requiring additional complexity in the decoding circuitry, which may be substantial, especially if the memory module is complex.

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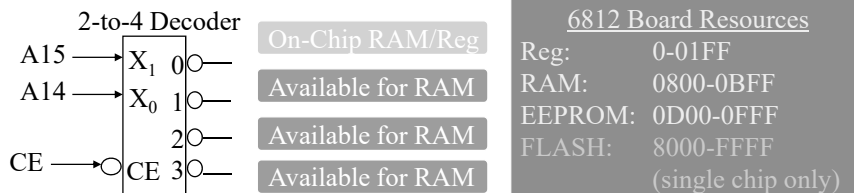
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## Alternatives to Decoding by Basic Logic Chips (use a Decoder!)

Example: Add an additional 16K of memory. Where can we place it?

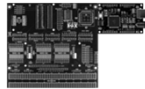


- ❖ If  $\{A_{15}-A_{14}\} = 00$ , the address range will be 0000 0000 to 0011 1111 1111 1111 -or- \$0000 to \$3FFF
- ❖ If  $\{A_{15}-A_{14}\} = 01$ , the address range will be 0100 0000 to 0111 1111 1111 1111 -or- \$4000 to \$7FFF
- ❖ If  $\{A_{15}-A_{14}\} = 10$ , the address range will be 1000 0000 to 1011 1111 1111 1111 -or- \$8000 to \$BFFF
- ❖ If  $\{A_{15}-A_{14}\} = 11$ , the address range will be 1100 0000 to 1111 1111 1111 1111 -or- \$C000 to \$FFFF

6811 Board Resources	
Reg:	1000-103F
RAM:	0-01FF
EEPROM:	B600-B7FF
ROM:	D000-FFFF
Only decoder output "1" can be used for RAM	

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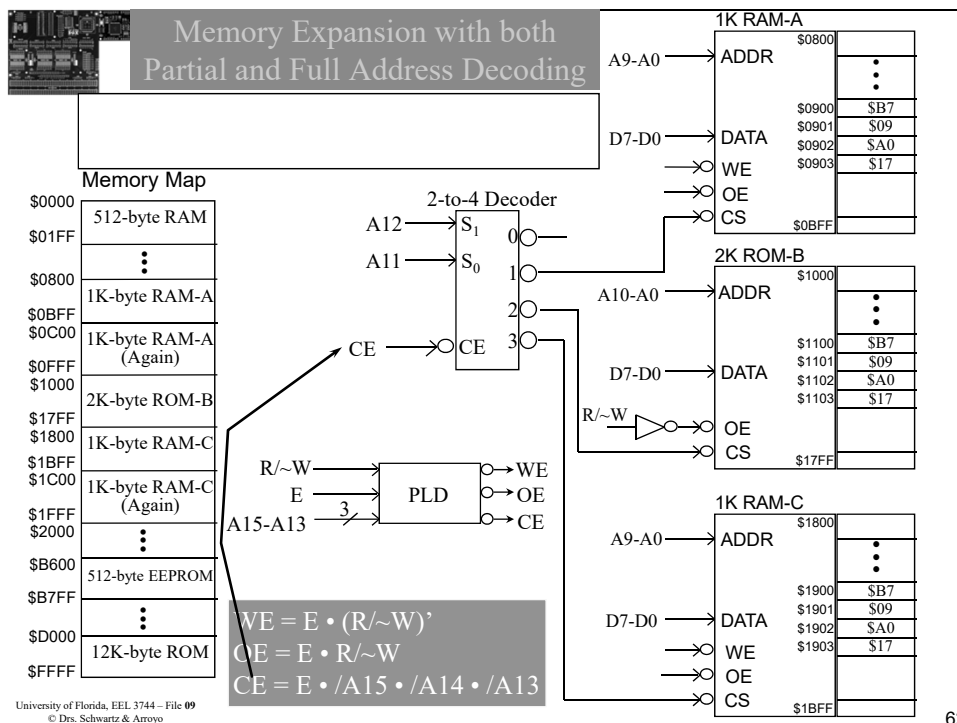
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## Memory Expansion with both Partial and Full Address Decoding

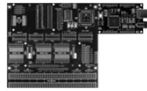
**[Example]** A system memory module comprises three memory units: two 1K-byte RAMs and a single 2K-byte ROM. **A mixture of fully decoded and partially decoded schemes is used.** Note that for a memory referenced by the  $\mu$ P, the E-clock signal must be high (when accessing memory) to enable the 2-to-4 decoder, which in turn controls the enabling of the individual memory units.

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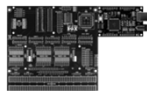


## EEL3744 Memory Expansion with both Partial and Full Address Decoding

- (1) For memory unit ROM-B (2K-byte), every bit of the 16-bit address is used to specify a location:
- $\{A_{15} = 0, A_{14} = 0, A_{13} = 0\} \rightarrow$  to enable the decoder
  - $\{A_{12} = 1, A_{11} = 0\} \rightarrow$  the inputs to activate decoder output 2
  - $\{A_{10} \sim A_0\} \rightarrow$  the actual address within ROM-B
- Therefore, the address range for ROM-B is from %0001 0000 0000 0000 to %0001 0111 1111 1111 (\$1000 to \$17FF). Also, since a ROM is read-only, just the inverted R/~W signal from the  $\mu$ P control bus is required to be connected to the output enable (OE) of the ROM.
- (2) For memory unit RAM-A, every bit of the 16-bit address, **except**  $A_{10}$  is used to specify a location:
- $\{A_{15} = 0, A_{14} = 0, A_{13} = 0\} \rightarrow$  to enable the decoder
  - $\{A_{12} = 0, A_{11} = 1\} \rightarrow$  the inputs to activate decoder output 1
  - $\{A_{10}\} \rightarrow$  Don't Care
  - $\{A_9 \sim A_0\} \rightarrow$  the actual address within RAM-A
- Since the addresses for RAM-A are **partially decoded**, each location has **two** different addresses. the addresses range from \$0800 to \$0BFF, and repeat from \$0C00 to \$0FFF.

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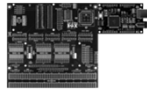
## EEL3744 Memory Expansion with both Partial and Full Address Decoding (continued)

- (3) The operation of RAM-C is similar to that of RAM-A. Each location in RAM-C also has **two** different addresses. These addresses range from \$1800 to \$1BFF, and repeat from \$1C00 to \$1FFF. This repeating is a result of  $A_{10}$  being a don't care. Also, address bits  $A_{11}$  and  $A_{12}$  must both be 1 to activate the appropriate decoder output 3 to enable the RAM-C chip enable (CE) input.

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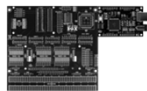
## EEL3744

## Memory Expansion with both Partial and Full Address Decoding (continued)

- The addresses in the range \$0200 to \$07FF are not valid since the corresponding decoder output 0 does not enable any memory unit
  - > Recall the M68HC11E9 has 512-byte of RAM from \$0000 to \$01FF
- Any address greater than \$1FFF (except for those for the on-board 512-byte EEPROM at \$B600-\$B7FF and the 12K ROM from \$D000-\$FFFF) is invalid since no memory unit is enabled.
  - > For each of these addresses, at least one of A15, A14, and A13 is non-zero, which prevents the enabling of the 2-to-4 decoder.
- **Question:** What if the CS input of RAM-A was connected to the decoder output 0 instead of to decoder output 1?
- **Answer:**
  - > Obviously, the memory map for the mP would change.
  - > Then the address range for RAM-A would become \$0000 to \$07FF, and the addresses \$0800 to \$0FFF would become invalid. (cont.)

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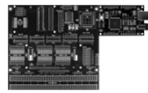
## EEL3744

## Memory Expansion with both Partial and Full Address Decoding (continued)

- Since there is on-board RAM located from \$0000 to \$01FF, any address within this internal RAM range addresses the **on-board** RAM and not the external RAM-A memory module resulting in a 512-byte loss of the 1K RAM-A space.
- Conceptually, the memory module can be configured and the addresses can be decoded in any manner desired by the  $\mu$ P system designer.
- However, the addresses referred in the software programs must be consistent with the hardware configuration. In other words, **the data must be where the program “thinks” it is.**
- The key point here is that the  $\mu$ P system designer must be aware of the hardware/software interaction that is inherent in the design of a  $\mu$ P system.

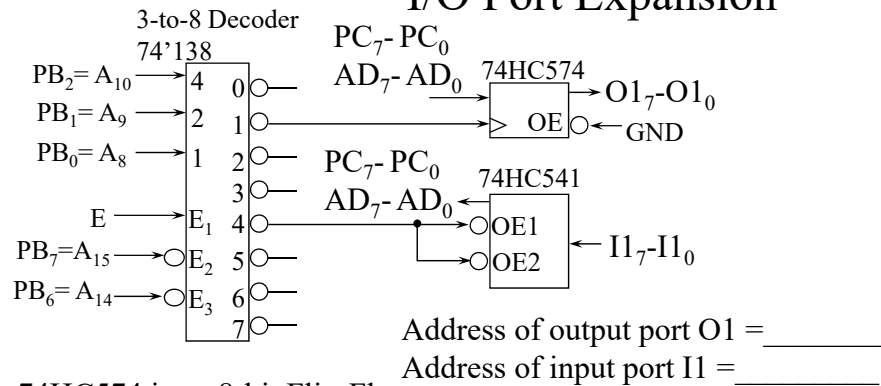
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## EEL3744 Creative Interfacing: 68HC11

### I/O Port Expansion

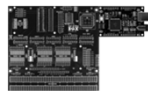


- 74HC574 is an 8-bit Flip-Flop
- 74HC541 is an 8-bit Tri-State Buffer (not in your parts kit)

Address of O1 = 00XX X001 XXXX XXXX  
 For example: \$01XX, \$11XX, \$39XX  
 Address of I1 = 00XX X100 XXXX XXXX  
 For example: \$04XX, \$14XX, \$3CXX

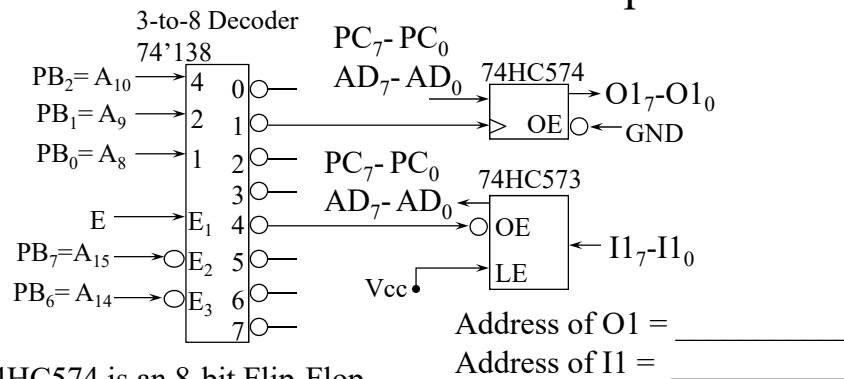
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## EEL3744 Creative Interfacing: 68HC11

### I/O Port Expansion



- 74HC574 is an 8-bit Flip-Flop
- 74HC573 is an 8-bit Tri-State Buffer

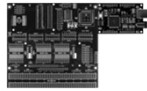
Addr of O1 = 00XX X001 XXXX XXXX  
 For example: \$01XX, \$11XX, \$39XX  
 Addr of I1 = 00XX X100 XXXX XXXX  
 For example: \$04XX, \$14XX, \$3CXX

74'573

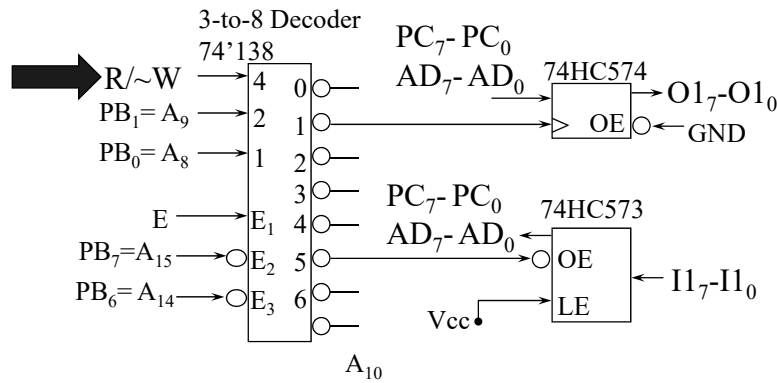
OE(L)	LE(H)	D <sub>i</sub> (H)	Q <sub>i</sub> (H)
0=H	X	X	Z
1=L	0=L	X	Q <sub>i</sub>
1=L	1=H	D <sub>i</sub>	D <sub>i</sub>

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## EEL3744 Creative Interfacing: 68HC11 I/O Port Expansion



Address of O1 = 00XX XX01 XXXX XXXX

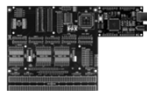
Examples: 0000 0001 0000 0000 = \$0100, \$3DFF

Address of I1 = 00XX XX01 XXXX XXXX

Examples: 0000 0001 0000 0000 = \$0100, \$3DFF

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## EEL3744 Looking Ahead

### **Lab 2: Use Built-in Ports for Inputs and Outputs (plus LSA)**

- Use Atmel XMEGA I/O Ports with LEDs

### **Lab 3: EBI (RAM Expansion) and Timers**

- Find non-conflicting address for SRAM; timers instead of timing loop

### **Lab 4: External Interrupts & PWM**

- External interrupts
- PWM for dynamic RGB LED control

### **Lab 5: Serial Communication and Accelerometer (UART & SPI)**

- Asynchronous serial communication with interrupts (SCI or other)
- SPI with IMU's accelerometer
- Using C for the first time

### **Lab 6: DAC & DMA (making music!)**

- Digital to analog; direct memory access; timers; create musical keyboard

### **Lab 7: ADC & DMA with SPI Flash ROM**

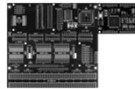
- Analog to digital conversion
- Use output timing system to generate waveforms to speaker (music!)

### **Lab 8: Multitasking**

- TBD

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See doc8385,  
Section 28

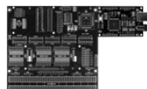
See doc8331,  
Section 27

## XMEGA's EBI: External Bus Interface

- Read **the entire** section 27 in doc8331!
- Many external device options are available
  - > Use the external memory address range
    - 0x4000 through 0xFF FFFF
    - 0x4000 through 0x4FFF is  $2^{12} = 4k = 4096$ 
      - $2^{12}$  because 12 bits go through all possible values
    - 0x1 0000 through 0x1 FFFF is  $2^{16} = 64k = 65,536$
    - Therefore, 0x4000 through 0xFF FFFF gives
 
$$64k * 256 - 4 * 4k = 2^{16} \times 2^8 - 16k = 2^{24} = 16M - 16k$$
 (where  $M = 2^{20}$ ,  $k = 2^{10}$ )
- A write to SRAM takes 1 cycle and a read from SRAM takes 2 cycles

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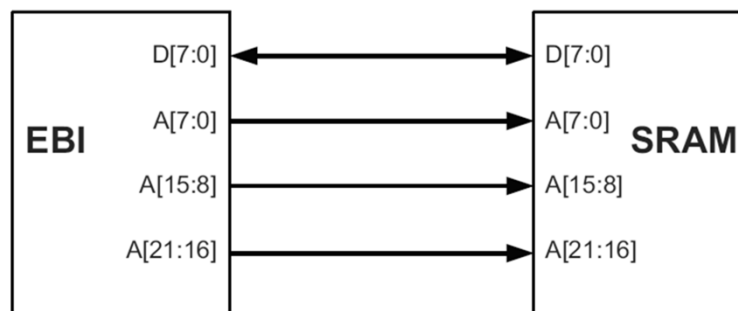


EEL3744

See doc8331,  
Figure 27-3

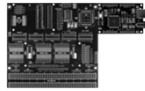
## XMEGA's EBI: External Bus Interface

- Non-multiplexed SRAM connection



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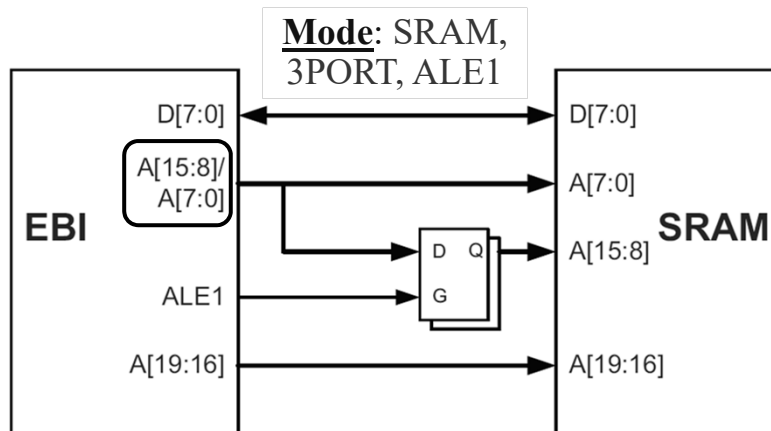
EEL3744

XMEGA's EBI:

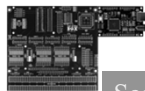
See doc8331,  
Figure 27-4

## External Bus Interface

- Multiplexed SRAM connection using ALE1
  - > Our **uPad** uses **this** multiplexed expansion mode!

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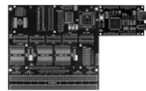
XMEGA's EBI: Pin-out  
for SRAMSee doc8331,  
Table 27-4See doc8385,  
Sec 33.2

- Our uPad uses PortH (Port0), PortJ (Port1), and PortK (Port 2) as described below
  - > ALE's are **active-high**; some manuals are **wrong**

PORT	PIN	SRAM 3PORT ALE1	SRAM 3PORT ALE12	SRAM 4PORT ALE2	SRAM 4PORT NOALE
PORT3 (Port E or F)	7:0	–	–	A[15:8]	A[15:8]
PORT2 (Port K)	7:0	A[7:0]/ A[15:8]	A[7:0]/ A[15:8]/ A[23:16]	A[7:0]/ A[23:16]	A[7:0]
PORT1 (Port J)	7:0	D[7:0]	D[7:0]	D[7:0]	D[7:0]
	7:4	$\overline{CS}[3:0]$ (A[19:16])	$\overline{CS}[3:0]$	$\overline{CS}[3:0]$	$\overline{CS}[3:0]$ (A[21:18])
PORT0 (Port H)	3	–	ALE2	ALE2	A17
	2	ALE1	ALE1	–	A16
	1	RE	RE	RE	RE
	0	WE	WE	WE	WE

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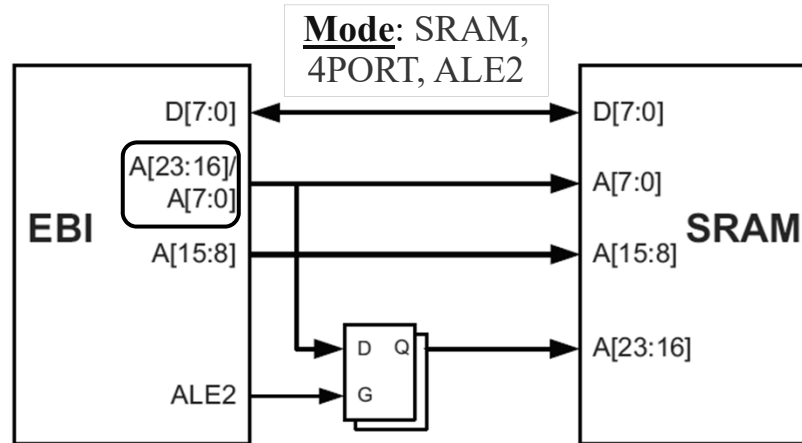


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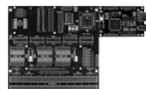
See doc8331,  
Figure 27-5

## XMEGA's EBI: External Bus Interface

- Multiplexed SRAM connection using ALE2

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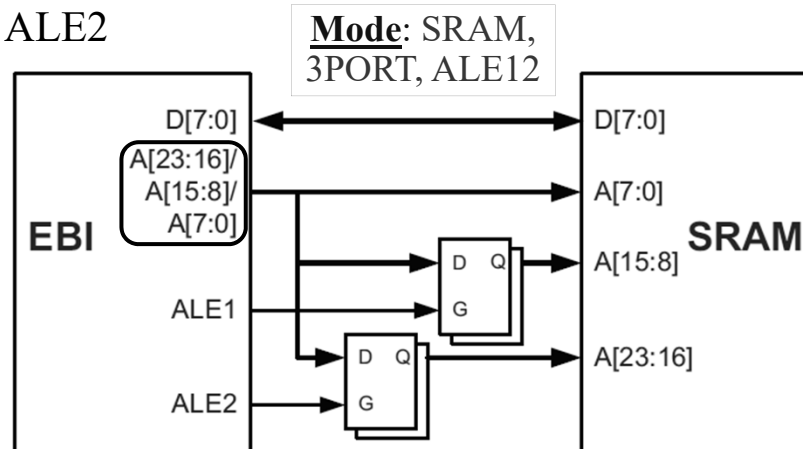


EEL3744

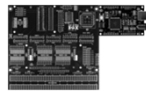
See doc8331,  
Figure 27-6

## XMEGA's EBI: External Bus Interface

- Multiplexed SRAM connection using ALE1 and ALE2

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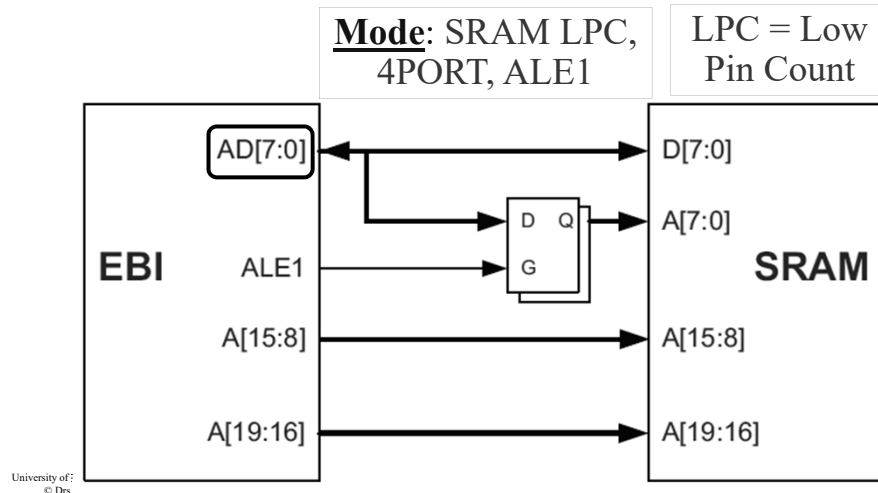


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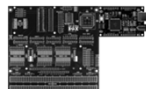
See doc8331,  
Figure 27-7

## XMEGA's EBI: External Bus Interface

- Multiplexed SRAM LPC connection using ALE1



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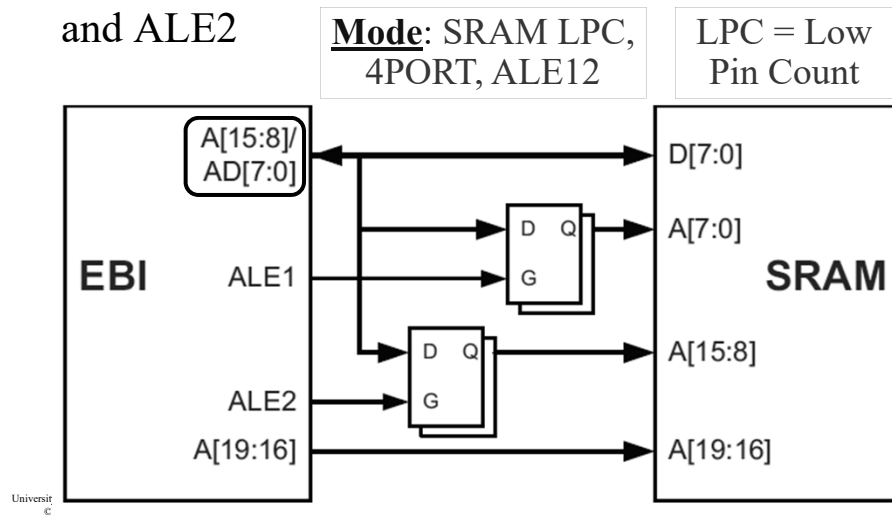


EEL3744

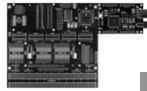
See doc8331,  
Figure 27-7

## XMEGA's EBI: External Bus Interface

- Multiplexed SRAM LPC connection using ALE1 and ALE2



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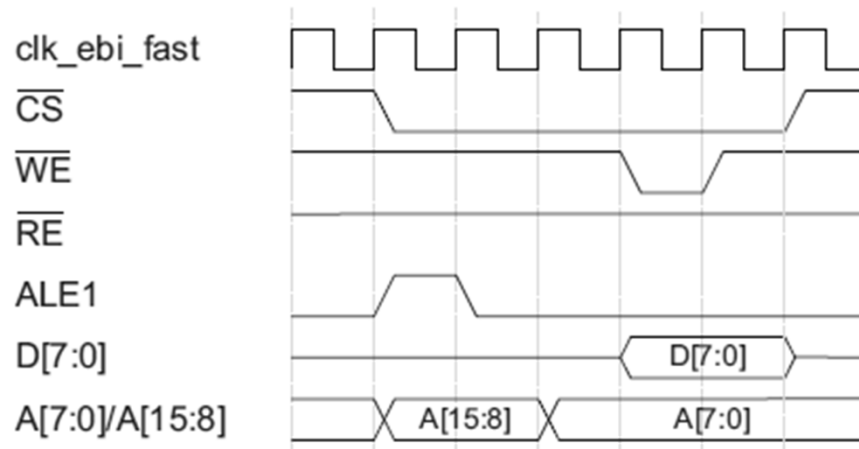


EEL3744

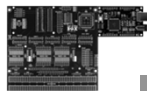
See doc8331,  
Section 36.1

## XMEGA Write (SRAM 3-Port ALE1) Timing Diagram

- Notice the ALE1(H) and WE(L) signals

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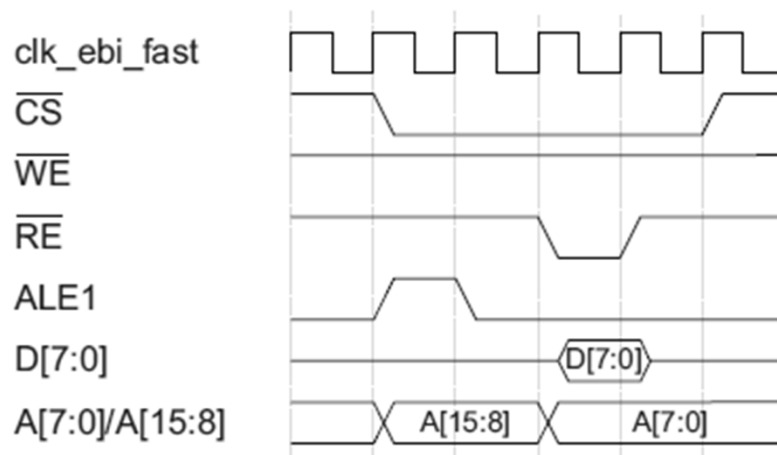


EEL3744

See doc8331,  
Section 36.1

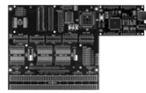
## XMEGA Read (SRAM 3-Port ALE1) Timing Diagram

- Notice the ALE1(H) and RE(L) signals

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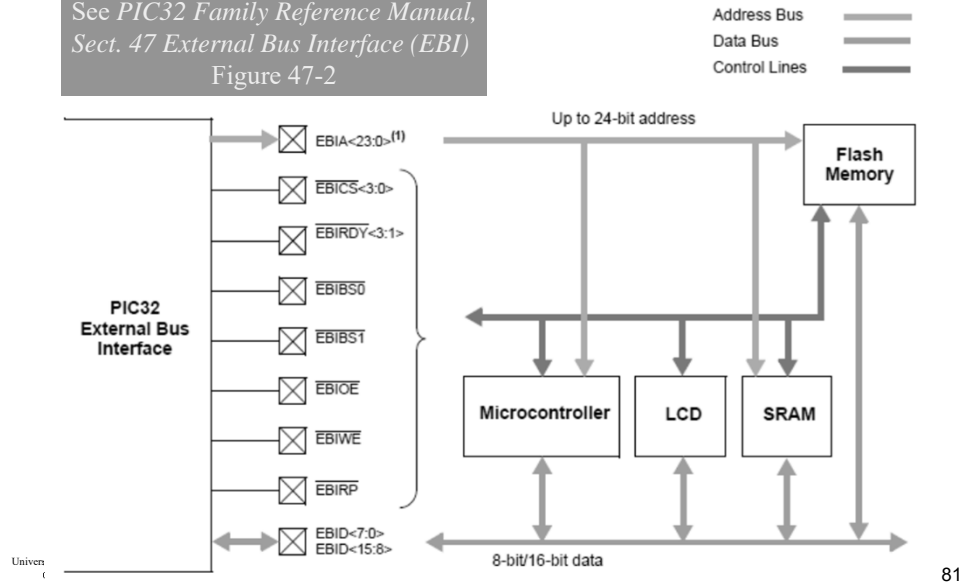
80



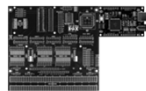


## EEL3744 (Microchip's) PIC32 EBI Connections

See *PIC32 Family Reference Manual*,  
Sect. 47 External Bus Interface (EBI)  
Figure 47-2

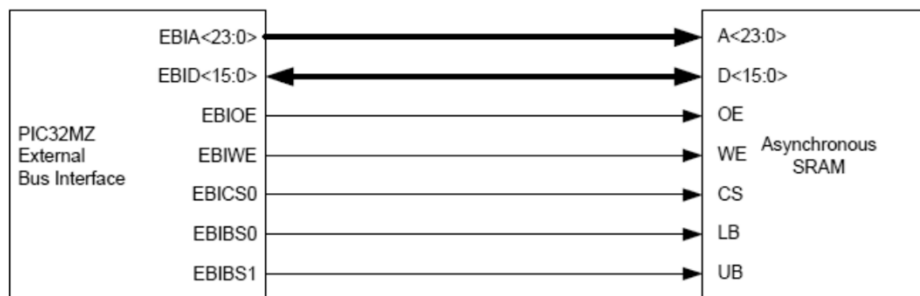


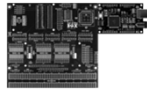
81



## EEL3744 PIC32 EBI Interface to Asynchronous SRAM

See *PIC32 Family Reference Manual*,  
Sect. 47 External Bus Interface (EBI)  
Figure 47-4



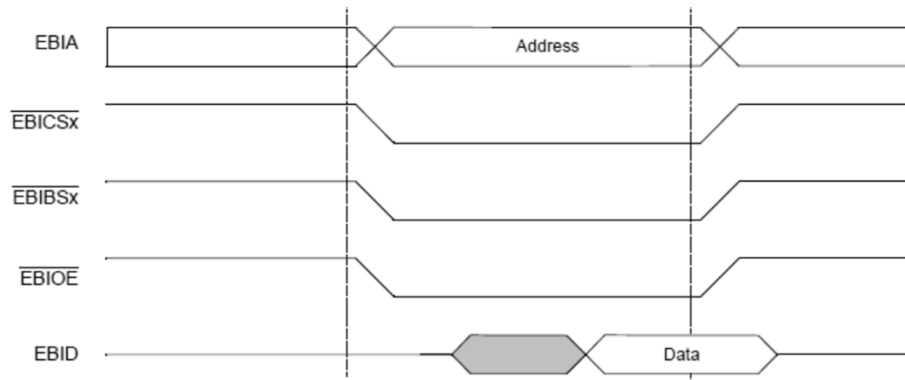


EEL3744

PIC32 EBI SRAM

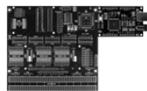
## Read Timing

See *PIC32 Family Reference Manual*,  
Sect. 47 External Bus Interface (EBI)  
Figure 47-9



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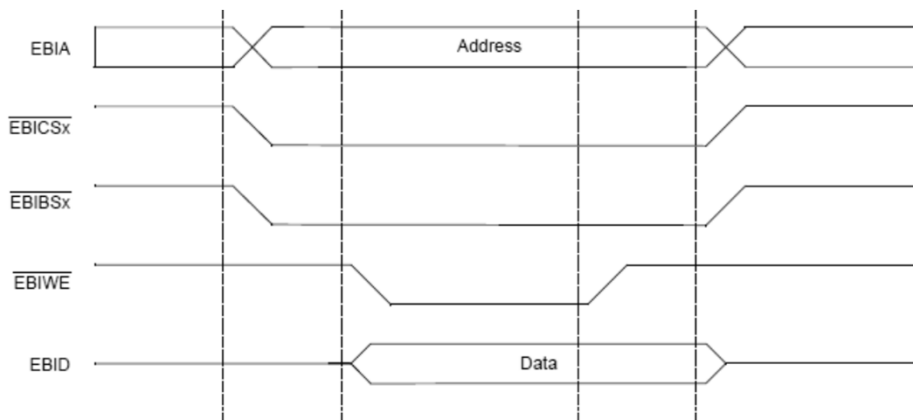


EEL3744

PIC32 EBI SRAM

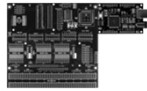
## Write Timing

See *PIC32 Family Reference Manual*,  
Sect. 47 External Bus Interface (EBI)  
Figure 47-11



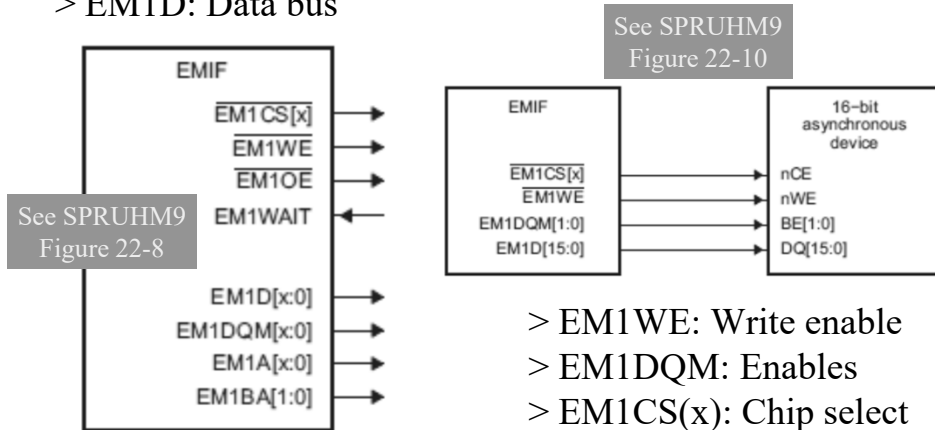
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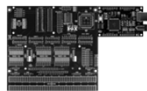
## EEL3744 (TI's) Piccolo EMIF Connections

- External Memory Interface (EMIF)
  - > EM1A: Address bus; EM1BA: Bank address b
  - > EM1D: Data bus

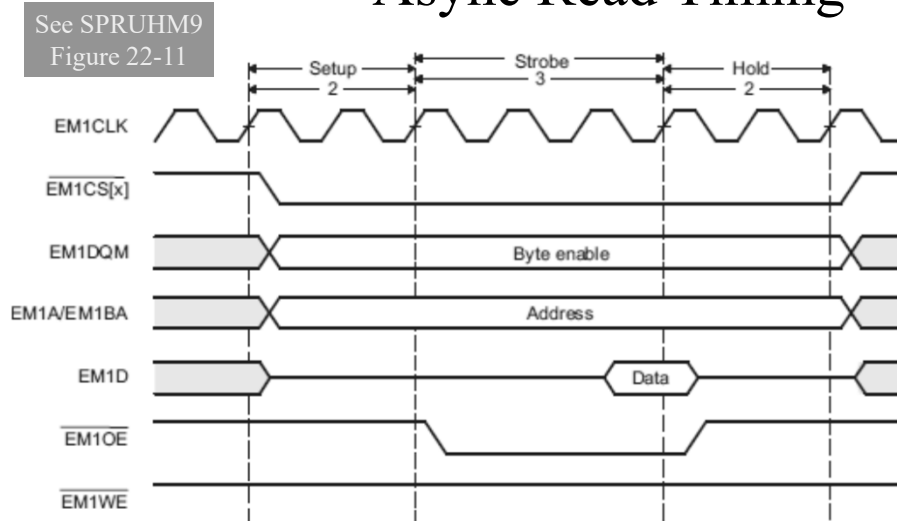


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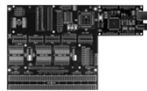


## EEL3744 (TI's) Piccolo EMIF Async Read Timing



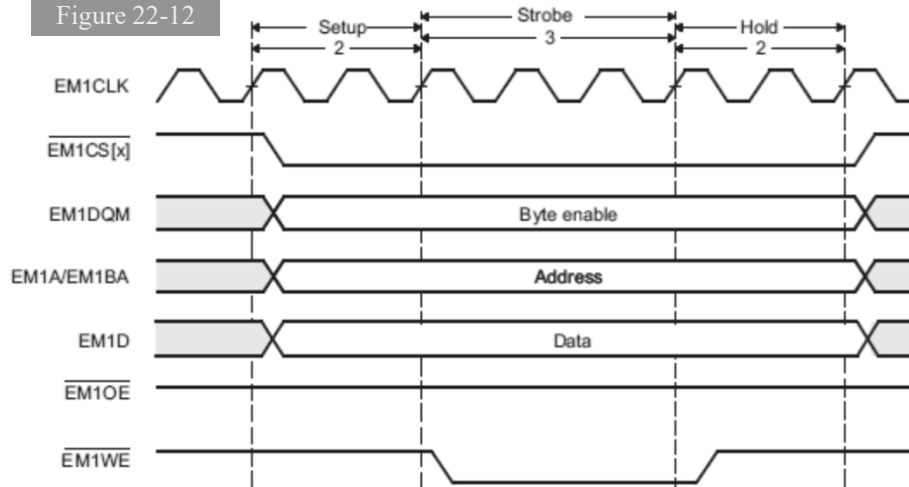
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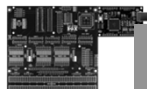
## EEL3744 (TI's) Piccolo EMIF Async Write Timing

See SPRUHM9  
Figure 22-12



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See doc8331,  
Section 27.10.1

## XMEGA EBI: CTRL – Control Register

### EBI\_CTRL

Bit	7	6	5	4	3	2	1	0	
+0x00	SDDATAW[1:0]		LPCMODE[1:0]		SRMODE[1:0]		IFMODE[1:0]		CTRL
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

- Bit 7:6 – SDDATAW[1:0]: SDRAM Data Width Setting
  - > **SDDATAW[1:0] = 00 for 4-bit data bus (we need for our uPad)**
  - > SDDATAW[1:0] = 01 for 8-bit data bus
  - > SDDATAW[1:0] = 1X not available
- Bit 5:4 – LPCMODE[1:0]: SRAM Low Pin Count Mode
  - > **LPCMODE[1:0] = 00 for ALE1 (Data multiplexed with Address byte 0)**
  - > LPCMODE[1:0] = X1 not available
  - > LPCMODE[1:0] = 10 for ALE1 and ALE2 (Data multiplexed with Address byte 0 and 1)

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Section 27.10.1

## XMEGA EBI: CTRL – Control Register

EBI\_CTRL

Bit	7	6	5	4	3	2	1	0	
+0x00	SDDATAW[1:0]		LPCMODE[1:0]		SRMODE[1:0]		IFMODE[1:0]		CTRL
Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W	
Initial Value	0	0	0	0	0	0	0	0	

- Bit 3:2 – SRAM Mode
  - > **SRMODE[1:0] = 00 for ALE1 (Address byte 0 and 1 multiplexed)**
  - > SRMODE[1:0] = 01 for ALE2 (Address byte 0 and 2 multiplexed)
  - > SRMODE[1:0] = 10 for ALE1 & 2 (Address byte 0, 1, & 2 multiplexed)
  - > SRMODE[1:0] = 11 for no ALE (No address multiplexing)
- Bit 1:0 – Interface Mode
  - > IFMODE[1:0] = 00 for DISABLED (EBI disabled)
  - > **IFMODE[1:0] = 01 for 3PORT (EBI enabled with three-port interface)**
  - > IFMODE[1:0] = 10 for 4PORT (EBI enabled with four-port interface)
  - > IFMODE[1:0] = 11 for 3PORT (EBI enabled with two-port interface)

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Section 27

## 3744 XMEGA EBI: CTRLA – Control Register A

EBI\_CSx\_CTRLA

Bit	7	6	5	4	3	2	1	0
+0x00	–		ASIZE[4:0]				MODE[1:0]	
Read/Write	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Initial Value	0	0	0	0	0	0	0	0

- Bit 6:2 – Address Size
  - > These bits select the address size for the chip select
  - > This is the size of the block above the base address

N = number of address bits in  
Address Size, i.e.,  $2^N = \text{Addr Size}$

**Example for 4K**

ASIZE	Group Config	Address Size	Addr Lines Compared
0 0000	256B	256B	ADDR[23:8]
0 0001	512B	512B	ADDR[23:9]
0 0010	1K	1K	ADDR[23:10]
0 0011	2K	2K	ADDR[23:11]
<b>0 0100</b>	<b>4K</b>	<b>4K</b>	<b>ADDR[23:12]</b>
N-8	$1K \times 2^{(N-10)}$	$1K \times 2^{(N-10)}$	ADDR[23:N]
1 0000	16M	16M	--
Other	--	--	Reserved

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Section 27

## 3744 XMEGA EBI: CTRLA –

### Control Register A

- Size of device → which address bits can be used for base address
- The base address for each chip select **must be on a 4KB boundary**

#### Examples:

- > For a 256 size, \$EF 37xx
  - But address \$EF 3yxx will work for all y!
- > For a 4K size, \$EF 3xxx
- > For a 64K, \$EF xxxx
- > For a 1M, \$Ex xxxx
- > **Anything less than 4k, it will still use 4k! (since only the top 4 nibbles are used)**

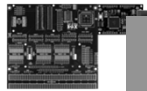
- Note that ALL unused address bits must have ALL values available
- N = number of address bits in Address Size, i.e.,  $2^N = \text{Addr Size}$

ASIZE	Group Config	Address Size	Addr Lines Compared
0 0000	256B	256B	ADDR[23:8]
0 0001	512B	512B	ADDR[23:9]
0 0010	1K	1K	ADDR[23:10]
0 0011	2K	2K	ADDR[23:11]
<b>0 0100</b>	<b>4K</b>	<b>4K</b>	<b>ADDR[23:12]</b>
N-8	$1K \times 2^{(N-10)}$	$1K \times 2^{(N-10)}$	ADDR[23:N]
1 0000	16M	16M	--
Other	--	--	Reserved

Example for 4K

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Section 27

## 4 XMEGA EBI: CTRLA –

### EBI\_CSx\_CTRLA

### Control Register A

Bit	7	6	5	4	3	2	1	0
+0x00	–	–	–	–	–	–	–	–
Read/Write	R	R/W	R/W	R/W	R/W	R/W	R/W	R/W
Initial Value	0	0	0	0	0	0	0	0

- Bit 1:0 – Chip Select Mode

- > These bits select the chip select mode and decide what type of interface is used for the external memory or peripheral

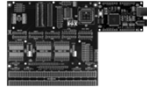
MODE	Group Config	Description
00	DISABLE	Chip select disabled
<b>01</b>	<b>SRAM</b>	<b>Enable chip select for SRAM</b>
10	LPC	Enable chip select for SRAM LPC
11	SDRAM	Enable chip select for SDRAM

Need for  
our labs

Ex: EBI\_CS0\_CTRLA

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See doc8385,  
Tables 33-7

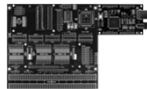
## XMEGA Port H Alternate Functions (for expansion)

- See Table 33-7, column “SRAM ALE1” for relevant control pins for using address/data busses

Port H	Pin #	SDRAM 3P	SRAM ALE1	SRAM ALE12	LPC3 ALE1	LPC2 ALE12
GND	53					
VCC	54					
PH0	55	WE(L)	WE(L)	WE(L)	WE(L)	WE(L)
PH1	56	CAS(L)	RE(L)	RE(L)	RE(L)	RE(L)
PH2	57	RAS(L)	ALE1(H)	ALE1(H)	ALE1(H)	ALE1(H)
PH3	58	DQM(L)		ALE2(H)		ALE2(H)
PH4	59	BA0	CS0(L)/A16	CS0(L)	CS0(L)	CS0(L)/A16
PH5	60	BA1	CS1(L)/A17	CS1(L)	CS1(L)	CS1(L)/A17
PH6	61	CKE	CS2(L)/A18	CS2(L)	CS2(L)	CS2(L)/A18
PH7	62	CLK	CS3(L)/A19	CS3(L)	CS3(L)	CS3(L)/A19

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See doc8385,  
Tables 33-8

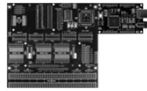
## XMEGA Port J Alternate Functions (for expansion)

- See Table 33-8, column “SRAM ALE1” for using address/data busses

Port J	Pin #	SDRAM 3P	SRAM ALE1 (or 2)	LPC3 (or 2) ALE1	LPC2 ALE12
GND	63				
VCC	64				
PJ0	65	D0	D0	D0/A0	D0/A0/A8
PJ1	66	D1	D1	D1/A1	D1/A1/A9
PJ2	67	D2	D2	D2/A2	D2/A2/A10
PJ3	68	D3	D3	D3/A3	D3/A3/A11
PJ4	69	A8	D4	D4/A4	D4/A4/A12
PJ5	70	A9	D5	D5/A5	D5/A5/A13
PJ6	71	A10	D6	D6/A6	D6/A6/A14
PJ7	72	A11	D7	D7/A7	D7/A7/A15

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See doc8385,  
Tables 33-9

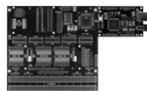
## XMEGA Port K Alternate Functions (for expansion)

- See Table 33-9, column “SRAM ALE1” for using address bus

Port K	Pin #	SDRAM 3P	SRAM ALE1	SRAM ALE2	LPC3 ALE1
GND	73				
VCC	74				
PK0	75	A0	A0/A8	A0/A8/A16	A8
PK1	76	A1	A1/A9	A1/A9/A17	A9
PK2	77	A2	A2/A10	A2/A10/A18	A10
PK3	78	A3	A3/A11	A3/A11/A19	A11
PK4	79	A4	A4/A12	A4/A12/A20	A12
PK5	80	A5	A5/A13	A5/A13/A21	A13
PK6	81	A6	A6/A14	A6/A14/A22	A14
PK7	82	A7	A7/A15	A7/A15/A23	A15

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Input\_Port.asm

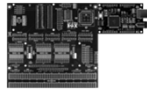
## XMEGA EBI Chip Select Base Address

- When setting up EBI for a specific chip select, the base address for that chip select must be chosen to initialize and reserve an address range that will trigger the correct chip select lines
- The base address will be used with the settings in EBI\_CSx\_CTRLA to determine a block of addresses for a specific chip select ( $x = 0, 1, 2, \text{ or } 3$ )
- The base address has the following properties
  - > Consists of up to 12 ( $=24-n$ ) bits for the address,  $A_{23}:A_n$  ( $n=12, 13, \dots$ )
    - The lower  $n$  bits  $A_{n-1}:A_0$  are assumed to be zero

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## XMEGA EBI Chip

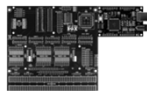
Input\_Port.asm

## Select Base Address

- First, we define the first address that external memory can be placed, which will become the base address, e.g.,  
`.set IN_PORT = 0x37E000`
- Next, we have to point to the address which holds the desired chip selects base address
  - > We use ZH and ZL registers to hold the high and low address components of EBI\_CSx\_BASEADDR (x = 0, 1, 2, or 3) [could use X or Y instead of Z], i.e.,  
`ldi ZH, HIGH(EBI_CS0_BASEADDR)`  
`ldi ZL, LOW(EBI_CS0_BASEADDR)`

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## XMEGA EBI Chip

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## Select Base Address

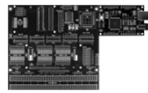
```
ldi ZH, HIGH(EBI_CS0_BASEADDR)
ldi ZL, LOW(EBI_CS0_BASEADDR)
```

- After above, Z points to the lower byte of the desired Chip Select Base Address
- We now want to load the chosen base address using Z (or X or Y)
  - > Use only the **top 12 bits**

ADDR Name	Value
EBI_CS0_BASEADDR (Lower)	??
EBI_CS0_BASEADDR (Upper)	??
EBI_CS1_BASEADDR (Lower)	??
EBI_CS1_BASEADDR (Upper)	??
EBI_CS2_BASEADDR (Lower)	??
EBI_CS2_BASEADDR (Upper)	??
EBI_CS3_BASEADDR (Lower)	??
EBI_CS3_BASEADDR (Upper)	??

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Input\_Port.asm

## XMEGA EBI Chip

## Select Base Address

- First take the middle byte of the 24 bit address (A15:8), and then store it, i.e.,

```
ldi R16, byte2(IN_PORT)  
st Z+, R16
```

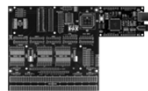
- > For example, with IOPORT = 0x37E000  
– R16 = 0xE0

- This will be stored to the location pointed to by Z
- Z is then incremented to point at the **upper byte** of the base address

ADDR Name	Value
EBI_CS0_BASEADDR (Lower)	<b>0xE0</b>
EBI_CS0_BASEADDR(Upper)	??
EBI_CS1_BASEADDR (Lower)	??
EBI_CS1_BASEADDR (Upper)	??
...	...

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Input\_Port.asm

## XMEGA EBI Chip

## Select Base Address

- Next we shift the desired base address by 16 bits, load into a register, i.e.,

```
ldi R16, byte3(IN_PORT)  
st Z, R16
```

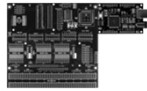
- > For example, with IOPORT = 0x37E000  
– R16 = 0x37

- This will be stored to the location pointed to by Z

ADDR Name	Value
EBI_CS0_BASEADDR (Lower)	0xE0
<b>EBI_CS0_BASEADDR(Upper)</b>	<b>0x37</b>
EBI_CS1_BASEADDR (Lower)	??
EBI_CS1_BASEADDR (Upper)	??
...	...

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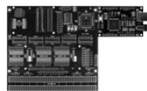
## XMEGA EBI Chip Select Base Address

Input\_Port.asm

- If your desired base address is only two bytes, only the top nibble will matter
  - > For example, only the 0x7 of 0x7000 would be used
- If a 3-byte base address is desired, for example 0x1E\_3000
  - > The top three nibbles are passed to the base address location, i.e., 0x1E3
  - > The chip select is triggered with any address starting at 0x1E\_3000 and going up to the size chosen in the EBI\_CTRLA register
    - If size = 16k, the CS (you might assume) is true for address 0x1E\_3000-0x1E\_6FFF; but this is **incorrect!** > 1 AND gate would be needed!
- You may hard code the values, but using the method shown in the **Input\_Port** example allows for more flexibility with base address values

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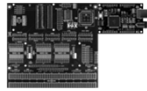
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## XMEGA EBI Chip Select (CS0-CS3)

- Each chip select **must start** at an address boundary
  - > The block size is determined by the address bits that can change
    - With the N changing address bits, the block size is  $2^N$
  - > The other bits A23:AN **must be fixed**
    - A 4k block can start anywhere in expansion memory, e.g., 0x4000, 0x5000, 0x6000, ... 0x1 0000, 0x2 0000, 0xF 0000, 0x10 0000, ..., 0x37 0000, ..., 0xFF 0000
      - The first hex digit does not change for any one of these
    - An 8k block can start at 0x4000, 0x6000, 0x8000, ...
      - It can **NOT** start at 0x5000, since the A15:A12 = 0101 or 0110
    - A 16k block can start at 0x4000, 0x8000, 0xC000, 0x1 0000, ...
      - It can **NOT** start at 0x5000, 0x6000, 0x7000
      - For a block starting at 0x4000, A15:A14=01

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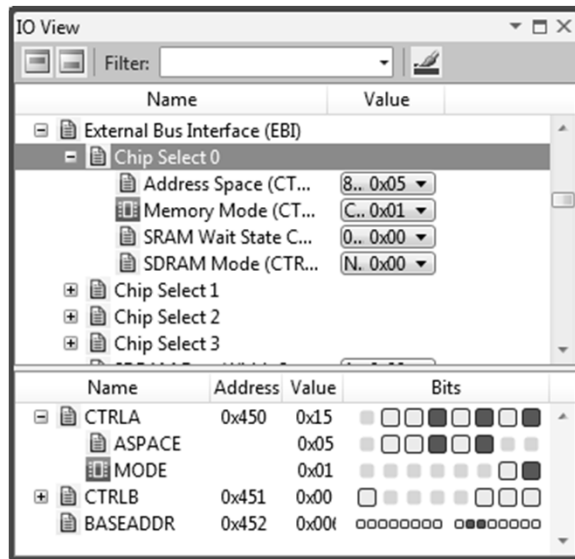
EEL3744



Input\_Port.asm

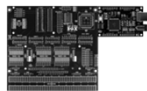
- When simulating in Atmel Studio, you can watch the EBI port using the IO View window and finding “External Bus Interface (EBI)”

## XMEGA EBI Chip Select Base Address



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# *The End!*

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